

# ISO642x General-Purpose, Basic and Reinforced, Dual-Channel Digital Isolators

## 1 Features

- [Functional Safety-Capable](#) (Planned)
  - Documentation available to aid IEC 61508 system design
- Up to 150Mbps data rate
- Robust SiO<sub>2</sub> isolation barrier:
  - Up to 5000V<sub>RMS</sub> isolation rating
  - Up to 10.4kV surge capability
  - Up to ±250kV/μs typical CMTI
  - Wide temperature range: –40°C to 125°C ambient operating
- Supply range: 2.25V to 5.5V
- [Overvoltage Tolerant Inputs](#)
- Default output *high* ( ISO642x ) and *low* ( ISO642xF ) options
- Low propagation delay: 10ns maximum at 5V, 12ns maximum at 3.3V
- Supports SPI up to: 25MHz at 5V, 20.8MHz at 3.3V
- Low pulse width distortion: 1.8ns maximum at 5V, 2.2ns maximum at 3.3V
- Robust electromagnetic compatibility (EMC)
  - System-level ESD, EFT, and surge immunity
  - Low emissions
- SOIC (D-8) Package
- Wide-SOIC (DWV-8) Package
- Safety-Related Certifications (Planned):
  - DIN EN IEC 60747-17 (VDE 0884-17)
  - UL 1577 and CSA CAS Notice No. 5A
  - IEC 62368-1, IEC 61010-1 and GB 4943.1 certifications

## 2 Applications

- [Power supplies](#)
- [Grid, Electricity meter](#)
- [Motor drives](#)
- [Factory automation](#)
- [Building automation](#)
- [Lighting](#)
- [Appliances](#)

## 3 Description

The ISO642x devices are general purpose digital isolators designed for applications requiring up to 5000V<sub>RMS</sub> isolation rating per UL 1577. The devices are also certified by VDE, TUV, and CQC.

The ISO642x devices provide high EMC performance while isolating CMOS or LVCMOS digital I/Os. ISO642x uses SiO<sub>2</sub> as the isolation barrier. Each isolation channel has a logic input and output buffer separated by the insulation barrier.

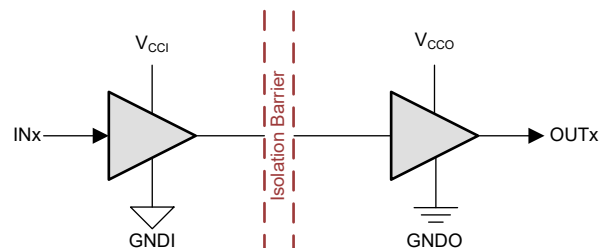
The ISO6420 and ISO6420F devices have all channels in the forward direction. The ISO6421 and ISO6421F devices have one reverse-direction channel.

In the event of input power or signal loss, the default output is *high* for devices without the suffix F and *low* for devices with the suffix F. See the [Device Functional Modes](#) section for further details.

### Package Information

| PART NUMBER <sup>(1)</sup> | PACKAGE                          | PACKAGE SIZE <sup>(2)</sup> |
|----------------------------|----------------------------------|-----------------------------|
| ISO6420 , ISO6420F         | SOIC (D-8) <sup>(3)</sup>        | 6mm × 4.9mm                 |
| ISO6421 , ISO6421F         | Wide-SOIC (DWV-8) <sup>(3)</sup> | 11.5mm × 5.85mm             |

- (1) For more information, see [Mechanical, Packaging, and Orderable Information](#).
- (2) The package size (length × width) is a nominal value and includes pins, where applicable.
- (3) Please refer to Packaging Information table on the Package Option Addendum page in the [Mechanical, Packaging, and Orderable Information](#) section for Production or Preproduction status for specific device and package.



V<sub>CCI</sub>=Input supply, V<sub>CCO</sub>=Output supply  
GNDI=Input ground, GNDO=Output ground

### Simplified Schematic



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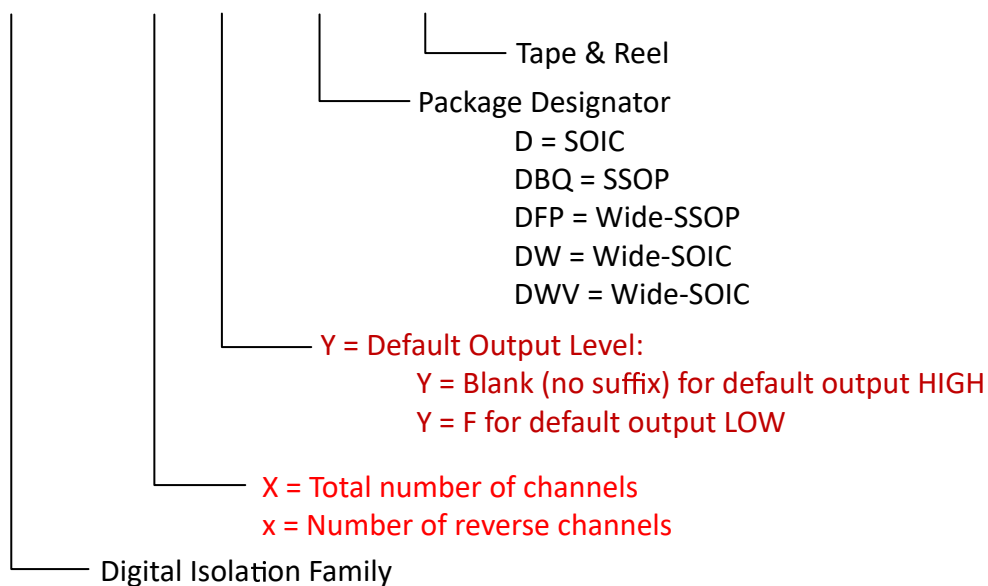
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## 4 Device Comparison

**Table 4-1. Device Comparison Table**

| DEVICE NAME                  | TOTAL CHANNELS | REVERSE CHANNELS | DEFAULT OUTPUT | PACKAGE           | CREEPAGE & CLEARANCE | VDE RATING | UL V <sub>ISO</sub>  | CMTI                                    |
|------------------------------|----------------|------------------|----------------|-------------------|----------------------|------------|----------------------|-----------------------------------------|
| <a href="#">ISO6420DR</a>    | 2              | 0                | HIGH           | SOIC (D-8)        | >4mm                 | Basic      | 3000V <sub>RMS</sub> | ±180kV/μs typical,<br>±150kV/μs minimum |
| <a href="#">ISO6420FDR</a>   |                |                  | LOW            |                   |                      |            |                      |                                         |
| <a href="#">ISO6421DR</a>    |                | 1                | HIGH           |                   |                      |            |                      |                                         |
| <a href="#">ISO6421FDR</a>   |                |                  | LOW            |                   |                      |            |                      |                                         |
| <a href="#">ISO6420DWVR</a>  | 2              | 0                | HIGH           | Wide-SOIC (DWV-8) | >8.5mm               | Reinforced | 5000V <sub>RMS</sub> | ±250kV/μs typical,<br>±200kV/μs minimum |
| <a href="#">ISO6420FDWVR</a> |                |                  | LOW            |                   |                      |            |                      |                                         |
| <a href="#">ISO6421DWVR</a>  |                | 1                | HIGH           |                   |                      |            |                      |                                         |
| <a href="#">ISO6421FDWVR</a> |                |                  | LOW            |                   |                      |            |                      |                                         |

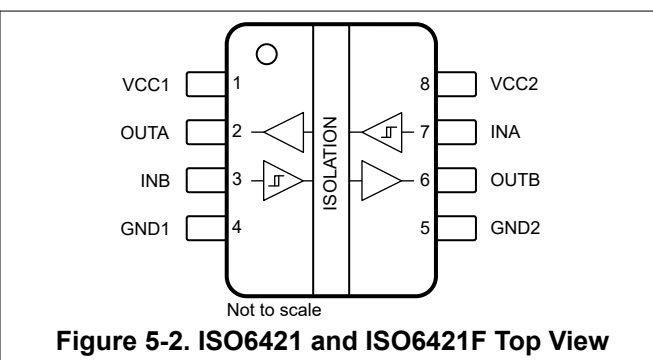
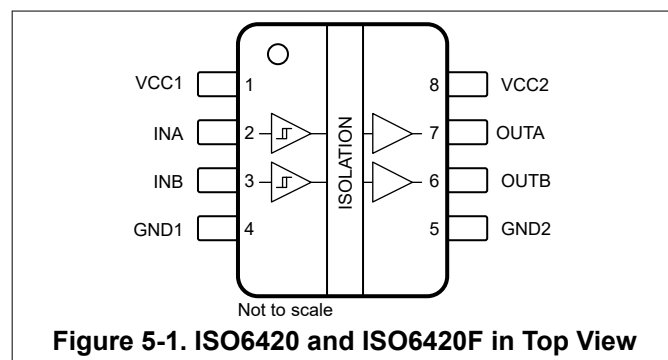
## ISO64 **Xx** **Y** PKG R



**Figure 4-1. Device Nomenclature**

## 5 Pin Configuration and Functions

### Pin Configuration for SOIC (D-8) and Wide-SOIC (DWV-8)



**Table 5-1. Pin Functions**

| NAME      | PIN                   |                       | Type <sup>(1)</sup> | DESCRIPTION                     |
|-----------|-----------------------|-----------------------|---------------------|---------------------------------|
|           | ISO6420 ,<br>ISO6420F | ISO6421 ,<br>ISO6421F |                     |                                 |
| GND1      | 4                     | 4                     | —                   | Ground connection for $V_{CC1}$ |
| GND2      | 5                     | 5                     | —                   | Ground connection for $V_{CC2}$ |
| INA       | 2                     | 7                     | I                   | Input, channel A                |
| INB       | 3                     | 3                     | I                   | Input, channel B                |
| OUTA      | 7                     | 2                     | O                   | Output, channel A               |
| OUTB      | 6                     | 6                     | O                   | Output, channel B               |
| $V_{CC1}$ | 1                     | 1                     | —                   | Power supply, $V_{CC1}$         |
| $V_{CC2}$ | 8                     | 8                     | —                   | Power supply, $V_{CC2}$         |

(1) I = Input, O = Output

## 6 Specifications

### 6.1 Absolute Maximum Ratings

See<sup>(1)</sup>

|                               |                                                | MIN  | MAX                                   | UNIT |
|-------------------------------|------------------------------------------------|------|---------------------------------------|------|
| Supply voltage <sup>(2)</sup> | V <sub>CC1</sub> to GND1                       | -0.5 | 6                                     | V    |
|                               | V <sub>CC2</sub> to GND2                       | -0.5 | 6                                     |      |
| Digital Input Voltage         | INx to GNDx                                    | -0.5 | 6                                     | V    |
| Digital Output Voltage        | OUTx to GNDx                                   | -0.5 | V <sub>CCX</sub> + 0.5 <sup>(3)</sup> | V    |
| Digital Output current        | I <sub>O</sub>                                 | -15  | 15                                    | mA   |
| Temperature                   | Operating junction temperature, T <sub>J</sub> |      | 150                                   | °C   |
|                               | Storage temperature, T <sub>stg</sub>          | -65  | 150                                   | °C   |

- (1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) All voltage values except differential I/O bus voltages are with respect to the local ground terminal (GND1 or GND2) and are peak voltage values
- (3) Maximum voltage must not exceed 6V.

### 6.2 ESD Ratings

|                    |                         |                                                                                          | VALUE | UNIT |
|--------------------|-------------------------|------------------------------------------------------------------------------------------|-------|------|
| V <sub>(ESD)</sub> | Electrostatic discharge | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins <sup>(1)</sup>              | ±2000 | V    |
|                    |                         | Charged device model (CDM), per JEDEC specification JESD22-C101, all pins <sup>(2)</sup> | ±1500 |      |

- (1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

|                     |                                                        |                                                            | MIN                        | NOM | MAX                  | UNIT |
|---------------------|--------------------------------------------------------|------------------------------------------------------------|----------------------------|-----|----------------------|------|
| $V_{CC\_RO}^{(1)}$  | Supply Voltage Side 1 (Recommended Operating Range)    | $V_{CC1} = 2.5V \text{ to } 5V^{(3)}$                      | 2.25                       |     | 5.5                  | V    |
|                     | Supply Voltage Side 2 (Recommended Operating Range)    | $V_{CC2} = 2.5V \text{ to } 5V^{(3)}$                      | 2.25                       |     | 5.5                  | V    |
| $V_{CC\_UVLO+}$     | $V_{CC}$ UVLO threshold when supply voltage is rising  |                                                            |                            |     | 2.24                 | V    |
| $V_{CC\_UVLO-}$     | $V_{CC}$ UVLO threshold when supply voltage is falling |                                                            | 1.6                        |     |                      | V    |
| $V_{CC\_UVLO\_HYS}$ | $V_{CC}$ Supply voltage UVLO hysteresis                |                                                            | 0.1                        |     |                      | V    |
| $V_{IH(INX)}$       | Input: High level Input voltage                        |                                                            | $0.7 \times V_{CCI}^{(2)}$ |     | $V_{CCI}$            | V    |
| $V_{IL(INX)}$       | Input: Low level Input voltage                         |                                                            | 0                          |     | $0.3 \times V_{CCI}$ | V    |
| $I_{OH}$            | Output: High level output current                      | $V_{CCO} = 5V^{(2)}$                                       | -4                         |     |                      | mA   |
|                     |                                                        | $V_{CCO} = 3.3V^{(2)}$                                     | -2                         |     |                      | mA   |
|                     |                                                        | $V_{CCO} = 2.5V^{(2)}$                                     | -1                         |     |                      | mA   |
| $I_{OL}$            | Output: Low level output current                       | $V_{CCO} = 5V^{(2)}$                                       |                            |     | 4                    | mA   |
|                     |                                                        | $V_{CCO} = 3.3V^{(2)}$                                     |                            |     | 2                    | mA   |
|                     |                                                        | $V_{CCO} = 2.5V^{(2)}$                                     |                            |     | 1                    | mA   |
| DR                  | Data Rate                                              | $3.0V \leq V_{CCx} \leq 5.5V$ and $C_L \leq 15pF^{(4)}$    | 0                          |     | 150                  | Mbps |
|                     |                                                        | $2.25V \leq V_{CCx} < 3V$ and $C_L \leq 10pF^{(4)}$        | 0                          |     | 150                  | Mbps |
|                     |                                                        | $2.25V \leq V_{CCx} < 3V$ and $10pF < C_L \leq 15pF^{(4)}$ | 0                          |     | 100                  | Mbps |
| $T_A$               | Ambient temperature                                    |                                                            | -40                        | 25  | 125                  | °C   |

(1)  $V_{CC1}$  and  $V_{CC2}$  can be set independent of one another

(2)  $V_{CCI} = \text{Input-side } V_{CC}$ ;  $V_{CCO} = \text{Output-side } V_{CC}$

(3) The channel outputs are in undetermined state when  $V_{CC\_UVLO-} \leq V_{CC1}$ ,  $V_{CC2} < V_{CC\_RO(MIN)}$ .

(4) See [Section 7](#).

### 6.4 Thermal Information

| PACKAGE         | PINS | THERMAL METRIC <sup>(1)</sup> |                      |                 |             |             |                      | UNIT |
|-----------------|------|-------------------------------|----------------------|-----------------|-------------|-------------|----------------------|------|
|                 |      | $R_{\theta JA}$               | $R_{\theta JC(top)}$ | $R_{\theta JB}$ | $\Psi_{JT}$ | $\Psi_{JB}$ | $R_{\theta JC(bot)}$ |      |
| D (SOIC)        | 8    | 139.7                         | 80.4                 | 87.6            | 38.8        | 85.9        | NA                   | °C/W |
| DWV (Wide-SOIC) | 8    | 128.1                         | 65.4                 | 86.9            | 40.9        | 84.4        | NA                   | °C/W |

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application note.

## 6.5 Power Ratings

| PARAMETER                                                        |                                        | TEST CONDITIONS                                                                                                                     | MIN | TYP | MAX   | UNIT |
|------------------------------------------------------------------|----------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------|-----|-----|-------|------|
| ISO6420 (default high) and ISO6420F (default low, with F suffix) |                                        |                                                                                                                                     |     |     |       |      |
| P <sub>D</sub>                                                   | Maximum power dissipation (both sides) | V <sub>CC1</sub> = V <sub>CC2</sub> = 5.5V, T <sub>J</sub> = 150°C, C <sub>L</sub> = 15pF, Input a 75MHz 50% duty cycle square wave |     |     | 134   | mW   |
| P <sub>D1</sub>                                                  | Maximum power dissipation (side-1)     |                                                                                                                                     |     |     | 31.9  | mW   |
| P <sub>D2</sub>                                                  | Maximum power dissipation (side-2)     |                                                                                                                                     |     |     | 102.1 | mW   |
| ISO6421 (default high) and ISO6421F (default low, with F suffix) |                                        |                                                                                                                                     |     |     |       |      |
| P <sub>D</sub>                                                   | Maximum power dissipation (both sides) | V <sub>CC1</sub> = V <sub>CC2</sub> = 5.5V, T <sub>J</sub> = 150°C, C <sub>L</sub> =15pF, Input a 75MHz 50% duty cycle square wave  |     |     | 142   | mW   |
| P <sub>D1</sub>                                                  | Maximum power dissipation (side-1)     |                                                                                                                                     |     |     | 71    | mW   |
| P <sub>D2</sub>                                                  | Maximum power dissipation (side-2)     |                                                                                                                                     |     |     | 71    | mW   |

## 6.6 Insulation Specifications

| PARAMETER                                        |                                                       | TEST CONDITIONS                                                                                                                                                                                                                                                                                                                                                   | PACKAGE           |                   | UNIT             |
|--------------------------------------------------|-------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------|-------------------|------------------|
|                                                  |                                                       |                                                                                                                                                                                                                                                                                                                                                                   | 8-D               | 8-DWV             |                  |
| IEC 60664-1                                      |                                                       |                                                                                                                                                                                                                                                                                                                                                                   |                   |                   |                  |
| CLR                                              | External clearance <sup>(1)</sup>                     | Side 1 to side 2 distance through air                                                                                                                                                                                                                                                                                                                             | >4                | >8.5              | mm               |
| CPG                                              | External creepage <sup>(1)</sup>                      | Side 1 to side 2 distance across package surface                                                                                                                                                                                                                                                                                                                  | >4                | >8.5              | mm               |
| DTI                                              | Distance through the insulation                       | Minimum internal gap (internal clearance)                                                                                                                                                                                                                                                                                                                         | >9                | >17               | μm               |
| CTI                                              | Comparative tracking index                            | IEC 60112                                                                                                                                                                                                                                                                                                                                                         | >600              | >600              | V                |
|                                                  | Material Group                                        | According to IEC 60664-1                                                                                                                                                                                                                                                                                                                                          | I                 | I                 |                  |
|                                                  | Overvoltage category                                  | Rated mains voltage ≤ 150V <sub>RMS</sub>                                                                                                                                                                                                                                                                                                                         | I-IV              | I-IV              |                  |
|                                                  |                                                       | Rated mains voltage ≤ 300V <sub>RMS</sub>                                                                                                                                                                                                                                                                                                                         | I-III             | I-IV              |                  |
|                                                  |                                                       | Rated mains voltage ≤ 600V <sub>RMS</sub>                                                                                                                                                                                                                                                                                                                         | n/a               | I-IV              |                  |
|                                                  |                                                       | Rated mains voltage ≤ 1000V <sub>RMS</sub>                                                                                                                                                                                                                                                                                                                        | n/a               | I-III             |                  |
| DIN EN IEC 60747-17 (VDE 0884-17) <sup>(2)</sup> |                                                       |                                                                                                                                                                                                                                                                                                                                                                   |                   |                   |                  |
| V <sub>IORM</sub>                                | Maximum repetitive peak isolation voltage             | AC voltage (bipolar)                                                                                                                                                                                                                                                                                                                                              | 707               | 1500              | V <sub>PK</sub>  |
| V <sub>IOWM</sub>                                | Maximum isolation working voltage                     | AC voltage (sine wave); time-dependent dielectric breakdown (TDDb) test.                                                                                                                                                                                                                                                                                          | 500               | 1061              | V <sub>RMS</sub> |
|                                                  |                                                       | DC voltage                                                                                                                                                                                                                                                                                                                                                        | 707               | 1500              | V <sub>DC</sub>  |
| V <sub>IOTM</sub>                                | Maximum transient isolation voltage                   | V <sub>TEST</sub> = V <sub>IOTM</sub> , t = 60s (qualification); V <sub>TEST</sub> = 1.2 × V <sub>IOTM</sub> , t= 1s (100% production)                                                                                                                                                                                                                            | 4243              | 7071              | V <sub>PK</sub>  |
| V <sub>IMP</sub>                                 | Maximum impulse voltage <sup>(3)</sup>                | Tested in air, 1.2/50μs waveform per IEC 62368-1                                                                                                                                                                                                                                                                                                                  | 4000              | 8000              | V <sub>PK</sub>  |
| V <sub>IOSM</sub>                                | Maximum surge isolation voltage <sup>(4)</sup>        | V <sub>IOSM</sub> ≥ 1.3 × V <sub>IMP</sub> ; Tested in oil (qualification test), 1.2/50μs waveform per IEC 62368-1                                                                                                                                                                                                                                                | 5200              | 10400             | V <sub>PK</sub>  |
| q <sub>pd</sub>                                  | Apparent charge <sup>(5)</sup>                        | Method a, After Input-output safety test subgroup 2/3, V <sub>ini</sub> = V <sub>IOTM</sub> , t <sub>ini</sub> = 60s; V <sub>pd(m)</sub> = 1.2 × V <sub>IORM</sub> , t <sub>m</sub> = 10s                                                                                                                                                                         | ≤5                | ≤5                | pC               |
|                                                  |                                                       | Method a, After environmental tests subgroup 1, V <sub>ini</sub> = V <sub>IOTM</sub> , t <sub>ini</sub> = 60s; V <sub>pd(m)</sub> = 1.6 × V <sub>IORM</sub> (for reinforced devices) or 1.2 × V <sub>IORM</sub> (for basic devices) for t <sub>m</sub> = 10s                                                                                                      | ≤5                | ≤5                |                  |
|                                                  |                                                       | Method b: At routine test (100% production); V <sub>ini</sub> = 1.2 × V <sub>IOTM</sub> , t <sub>ini</sub> = 1s; V <sub>pd(m)</sub> = 1.875 × V <sub>IORM</sub> (for reinforced devices) or 1.5 × V <sub>IORM</sub> (for basic devices), t <sub>m</sub> = 1s (method b1) or V <sub>pd(m)</sub> = V <sub>ini</sub> , t <sub>m</sub> = t <sub>ini</sub> (method b2) | ≤5                | ≤5                |                  |
| C <sub>IO</sub>                                  | Barrier capacitance, input to output <sup>(6)</sup>   | V <sub>IO</sub> = 0.4 × sin (2 πft), f = 1MHz                                                                                                                                                                                                                                                                                                                     | ≅1.1              | ≅0.9              | pF               |
| R <sub>IO</sub>                                  | Insulation resistance, input to output <sup>(6)</sup> | V <sub>IO</sub> = 500V, T <sub>A</sub> = 25°C                                                                                                                                                                                                                                                                                                                     | >10 <sup>12</sup> | >10 <sup>12</sup> | Ω                |
|                                                  |                                                       | V <sub>IO</sub> = 500V, 100°C ≤ T <sub>A</sub> ≤ 125°C                                                                                                                                                                                                                                                                                                            | >10 <sup>11</sup> | >10 <sup>11</sup> |                  |
|                                                  |                                                       | V <sub>IO</sub> = 500V at T <sub>S</sub> = 150°C                                                                                                                                                                                                                                                                                                                  | >10 <sup>9</sup>  | >10 <sup>9</sup>  |                  |
|                                                  | Pollution degree                                      |                                                                                                                                                                                                                                                                                                                                                                   | 2                 | 2                 |                  |
|                                                  | Climatic category                                     |                                                                                                                                                                                                                                                                                                                                                                   | 40/125/21         | 40/125/21         |                  |
| UL 1577                                          |                                                       |                                                                                                                                                                                                                                                                                                                                                                   |                   |                   |                  |
| V <sub>ISO</sub>                                 | Withstand isolation voltage                           | V <sub>TEST</sub> = V <sub>ISO</sub> , t = 60s (qualification); V <sub>TEST</sub> = 1.2 × V <sub>ISO</sub> , t = 1s (100% production)                                                                                                                                                                                                                             | 3000              | 5000              | V <sub>RMS</sub> |

- (1) Creepage and clearance requirements should be applied according to the specific equipment isolation standards of an application. Care should be taken to maintain the creepage and clearance distance of a board design to ensure that the mounting pads of the isolator on the printed-circuit board do not reduce this distance. Creepage and clearance on a printed-circuit board become equal in certain cases. Techniques such as inserting grooves, ribs, or both on a printed circuit board are used to help increase these specifications.
- (2) This digital isolator is suitable for *safe electrical insulation* (reinforced device) or *basic electrical insulation* (basic device) only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.
- (3) Testing is carried out in air to determine the surge immunity of the package.

- (4) Testing is carried out in oil to determine the intrinsic surge immunity of the isolation barrier.
- (5) Apparent charge is electrical discharge caused by a partial discharge (pd).
- (6) All pins on each side of the barrier tied together creating a two-pin device.

## 6.7 Safety-Related Certifications

| VDE                                                            | UL                                                             | CQC                                   | TUV                                                    |
|----------------------------------------------------------------|----------------------------------------------------------------|---------------------------------------|--------------------------------------------------------|
| Plan to certify according to DIN EN IEC 60747-17 (VDE 0884-17) | Plan to certify according to UL 1577 and CSA CAS Notice No. 5A | Plan to certify according to GB4943.1 | Plan to certify according to EN 61010-1 and EN 62368-1 |
| Certificate planned                                            | Certificate planned                                            | Certificate planned                   | Certificate planned                                    |

## 6.8 Safety Limiting Values

Safety limiting<sup>(1)</sup> intends to minimize potential damage to the isolation barrier upon failure of input or output circuitry.

| PARAMETER            |                                         | TEST CONDITIONS                                                                                                             | MIN | TYP | MAX   | UNIT               |
|----------------------|-----------------------------------------|-----------------------------------------------------------------------------------------------------------------------------|-----|-----|-------|--------------------|
| <b>D-8 Package</b>   |                                         |                                                                                                                             |     |     |       |                    |
| $I_S$                | Safety input, output, or supply current | $R_{\theta JA} = 139.7^{\circ}\text{C/W}$ , $V_I = 5.5\text{V}$ , $T_J = 150^{\circ}\text{C}$ , $T_A = 25^{\circ}\text{C}$  |     |     | 162.7 | mA                 |
|                      |                                         | $R_{\theta JA} = 139.7^{\circ}\text{C/W}$ , $V_I = 3.6\text{V}$ , $T_J = 150^{\circ}\text{C}$ , $T_A = 25^{\circ}\text{C}$  |     |     | 248.5 | mA                 |
|                      |                                         | $R_{\theta JA} = 139.7^{\circ}\text{C/W}$ , $V_I = 2.75\text{V}$ , $T_J = 150^{\circ}\text{C}$ , $T_A = 25^{\circ}\text{C}$ |     |     | 325.4 |                    |
| $P_S$                | Safety input, output, or total power    | $R_{\theta JA} = 139.7^{\circ}\text{C/W}$ , $T_J = 150^{\circ}\text{C}$ , $T_A = 25^{\circ}\text{C}$                        |     |     | 894.8 | mW                 |
| $T_S$                | Maximum safety temperature              |                                                                                                                             |     |     | 150   | $^{\circ}\text{C}$ |
| <b>DWV-8 Package</b> |                                         |                                                                                                                             |     |     |       |                    |
| $I_S$                | Safety input, output, or supply current | $R_{\theta JA} = 128.1^{\circ}\text{C/W}$ , $V_I = 5.5\text{V}$ , $T_J = 150^{\circ}\text{C}$ , $T_A = 25^{\circ}\text{C}$  |     |     | 177.4 | mA                 |
| $I_S$                | Safety input, output, or supply current | $R_{\theta JA} = 128.1^{\circ}\text{C/W}$ , $V_I = 3.6\text{V}$ , $T_J = 150^{\circ}\text{C}$ , $T_A = 25^{\circ}\text{C}$  |     |     | 271.1 | mA                 |
| $I_S$                | Safety input, output, or supply current | $R_{\theta JA} = 128.1^{\circ}\text{C/W}$ , $V_I = 2.75\text{V}$ , $T_J = 150^{\circ}\text{C}$ , $T_A = 25^{\circ}\text{C}$ |     |     | 354.8 | mA                 |
| $P_S$                | Safety input, output, or total power    | $R_{\theta JA} = 128.1^{\circ}\text{C/W}$ , $T_J = 150^{\circ}\text{C}$ , $T_A = 25^{\circ}\text{C}$                        |     |     | 975.8 | mW                 |
| $T_S$                | Maximum safety temperature              |                                                                                                                             |     |     | 150   | $^{\circ}\text{C}$ |

- (1) The maximum safety temperature,  $T_S$ , has the same value as the maximum junction temperature,  $T_J$ , specified for the device. The  $I_S$  and  $P_S$  parameters represent the safety current and safety power respectively. The maximum limits of  $I_S$  and  $P_S$  should not be exceeded. These limits vary with the ambient temperature,  $T_A$ .  
The junction-to-air thermal resistance,  $R_{\theta JA}$ , in the table is that of a device installed on a high-K test board for leaded surface-mount packages. Use these equations to calculate the value for each parameter:  
 $T_J = T_A + R_{\theta JA} \times P$ , where  $P$  is the power dissipated in the device.  
 $T_{J(\text{max})} = T_S = T_A + R_{\theta JA} \times P_S$ , where  $T_{J(\text{max})}$  is the maximum allowed junction temperature.  
 $P_S = I_S \times V_I$ , where  $V_I$  is the maximum input voltage.

## 6.9 Electrical Characteristics—5V Supply

$V_{CC1} = V_{CC2} = 5V \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER         |                                                                                     | TEST CONDITIONS                                                                                                    | MIN                        | TYP                        | MAX | UNIT        |
|-------------------|-------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------|----------------------------|----------------------------|-----|-------------|
| $V_{OH(OUTx)}$    | OUTx (output) high-level output voltage                                             | $I_{OH} = -4mA$ ; See <a href="#">Section 7</a>                                                                    | $V_{CCO} - 0.4^{(1)}$      |                            |     | V           |
| $V_{OL(OUTx)}$    | OUTx (output) low-level output voltage                                              | $I_{OL} = 4mA$ ; See <a href="#">Section 7</a>                                                                     |                            |                            | 0.4 |             |
| $V_{IT+(INx)}$    | INx (input) switching threshold voltage, rising                                     |                                                                                                                    |                            | $0.7 \times V_{CCI}^{(1)}$ |     |             |
| $V_{IT-(INx)}$    | INx (input) switching threshold voltage, falling                                    |                                                                                                                    | $0.3 \times V_{CCI}^{(1)}$ |                            |     |             |
| $V_{I\_HYS(INx)}$ | INx (input) switching threshold voltage hysteresis                                  |                                                                                                                    | $0.1 \times V_{CCI}^{(1)}$ |                            |     |             |
| $I_{I(INx)}$      | INx (input) input current (default high device)                                     | HIGH Input Current: $V_{IH} = V_{CCI}^{(1)}$ at INx (leakage current)                                              |                            |                            | 1   | $\mu A$     |
|                   |                                                                                     | LOW Input Current: $V_{IL} = 0V$ at INx (leakage and current through default high pull-up resistance)              | -10                        |                            |     |             |
|                   | INx (input) input current (default low device, with F suffix)                       | HIGH Input Current: $V_{IH} = V_{CCI}^{(1)}$ at INx (leakage and current through default low pull-down resistance) |                            |                            | 10  |             |
|                   |                                                                                     | LOW Input Current: $V_{IL} = 0V$ at INx (leakage current)                                                          | -1                         |                            |     |             |
| CMTI_R            | Common mode transient immunity, device rated for reinforced isolation (DWV Package) | $V_I = V_{CC}$ or 0V, $V_{CM} = 1200V$ ; See <a href="#">Section 7</a>                                             | 200                        | 250                        |     | kV/ $\mu s$ |
| CMTI_B            | Common mode transient immunity, device rated for basic isolation (D Package )       | $V_I = V_{CC}$ or 0V, $V_{CM} = 1200V$ ; See <a href="#">Section 7</a>                                             | 150                        | 180                        |     | kV/ $\mu s$ |
| $C_i$             | Input Capacitance <sup>(2)</sup>                                                    | $V_I = V_{CC}/2 + 0.4 \times \sin(2\pi ft)$ , $f = 2MHz$ , $V_{CC} = 5V$                                           |                            | 1.25                       |     | pF          |

(1)  $V_{CCI}$  = Input-side  $V_{CC}$ ;  $V_{CCO}$  = Output-side  $V_{CC}$

(2) Measured from input pin to same side ground.

## 6.10 Supply Current Characteristics—5V Supply

$V_{CC1} = V_{CC2} = 5V \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER                                                        | TEST CONDITIONS                                                                                                                                                   |         | SUPPLY CURRENT     | MIN | TYP  | MAX  | UNIT |
|------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------|--------------------|-----|------|------|------|
| ISO6420 (default high) and ISO6420F (default low, with F suffix) |                                                                                                                                                                   |         |                    |     |      |      |      |
| Supply current - DC signal                                       | $V_I = V_{CC1}$ <sup>(1)</sup> (default high); $V_I = 0V$ (default low, with F suffix)                                                                            |         | $I_{CC1}$          |     | 1.7  | 2.5  | mA   |
|                                                                  |                                                                                                                                                                   |         | $I_{CC2}$          |     | 0.7  | 0.9  |      |
|                                                                  | $V_I = 0V$ (default high); $V_I = V_{CC1}$ (default low, with F suffix)                                                                                           |         | $I_{CC1}$          |     | 5.3  | 6.6  |      |
|                                                                  |                                                                                                                                                                   |         | $I_{CC2}$          |     | 0.6  | 0.75 |      |
| Supply current - AC signal                                       | All channels switching with square wave clock input; $C_L = 15pF$                                                                                                 | 1Mbps   | $I_{CC1}$          |     | 3.8  | 4.45 |      |
|                                                                  |                                                                                                                                                                   |         | $I_{CC2}$          |     | 0.8  | 0.95 |      |
|                                                                  |                                                                                                                                                                   | 10Mbps  | $I_{CC1}$          |     | 3.8  | 4.55 |      |
|                                                                  |                                                                                                                                                                   |         | $I_{CC2}$          |     | 1.7  | 2    |      |
|                                                                  |                                                                                                                                                                   | 100Mbps | $I_{CC1}$          |     | 4.2  | 5.05 |      |
|                                                                  |                                                                                                                                                                   |         | $I_{CC2}$          |     | 10.9 | 12.5 |      |
| ISO6421 (default high) and ISO6421F (default low, with F suffix) |                                                                                                                                                                   |         |                    |     |      |      |      |
| Supply current - DC signal                                       | $V_I = V_{CC1}$ <sup>(1)</sup> (default high); $V_I = 0V$ (default low, with F suffix)<br>$V_I = 0V$ (default high); $V_I = V_{CC1}$ (default low, with F suffix) |         | $I_{CC1}, I_{CC2}$ |     | 1.7  | 2.45 | mA   |
|                                                                  |                                                                                                                                                                   |         | $I_{CC1}, I_{CC2}$ |     | 3.6  | 4.4  |      |
| Supply current - AC signal                                       | All channels switching with square wave clock input; $C_L = 15pF$                                                                                                 | 1Mbps   | $I_{CC1}, I_{CC2}$ |     | 2.8  | 3.4  |      |
|                                                                  |                                                                                                                                                                   | 10Mbps  | $I_{CC1}, I_{CC2}$ |     | 3.3  | 3.95 |      |
|                                                                  |                                                                                                                                                                   | 100Mbps | $I_{CC1}, I_{CC2}$ |     | 8.2  | 9.4  |      |

(1)  $V_{CCI} = \text{Input-side } V_{CC}$

## 6.11 Electrical Characteristics—3.3V Supply

$V_{CC1} = V_{CC2} = 3.3V \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER         |                                                                                     | TEST CONDITIONS                                                                                                    | MIN                        | TYP                        | MAX | UNIT        |
|-------------------|-------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------|----------------------------|----------------------------|-----|-------------|
| $V_{OH(OUTx)}$    | OUTx (output) high-level output voltage                                             | $I_{OH} = -2mA$ ; See <a href="#">Section 7</a>                                                                    | $V_{CCO} - 0.2^{(1)}$      |                            |     | V           |
| $V_{OL(OUTx)}$    | OUTx (output) low-level output voltage                                              | $I_{OL} = 2mA$ ; See <a href="#">Section 7</a>                                                                     |                            |                            | 0.2 |             |
| $V_{IT+(INx)}$    | INx (input) switching threshold voltage, rising                                     |                                                                                                                    |                            | $0.7 \times V_{CCI}^{(1)}$ |     |             |
| $V_{IT-(INx)}$    | INx (input) switching threshold voltage, falling                                    |                                                                                                                    | $0.3 \times V_{CCI}^{(1)}$ |                            |     |             |
| $V_{I\_HYS(INx)}$ | INx (input) switching threshold voltage hysteresis                                  |                                                                                                                    | $0.1 \times V_{CCI}^{(1)}$ |                            |     |             |
| $I_{I(INx)}$      | INx (input) input current (default high device)                                     | HIGH Input Current: $V_{IH} = V_{CCI}^{(1)}$ at INx (leakage current)                                              |                            |                            | 1   | $\mu A$     |
|                   |                                                                                     | LOW Input Current: $V_{IL} = 0V$ at INx (leakage and current through default high pull-up resistance)              | -10                        |                            |     |             |
|                   | INx (input) input current (default low device, with F suffix)                       | HIGH Input Current: $V_{IH} = V_{CCI}^{(1)}$ at INx (leakage and current through default low pull-down resistance) |                            |                            | 10  |             |
|                   |                                                                                     | LOW Input Current: $V_{IL} = 0V$ at INx (leakage current)                                                          | -1                         |                            |     |             |
| CMTI_R            | Common mode transient immunity, device rated for reinforced isolation (DWV Package) | $V_I = V_{CC}$ or $0V$ , $V_{CM} = 1200V$ ; See <a href="#">Section 7</a>                                          | 200                        | 250                        |     | kV/ $\mu s$ |
| CMTI_B            | Common mode transient immunity, device rated for basic isolation (D Package )       | $V_I = V_{CC}$ or $0V$ , $V_{CM} = 1200V$ ; See <a href="#">Section 7</a>                                          | 150                        | 180                        |     | kV/ $\mu s$ |
| $C_i$             | Input Capacitance <sup>(2)</sup>                                                    | $V_I = V_{CC}/2 + 0.4 \times \sin(2\pi ft)$ , $f = 2MHz$ , $V_{CC} = 3.3V$                                         |                            | 1.3                        |     | pF          |

(1)  $V_{CCI}$  = Input-side  $V_{CC}$ ;  $V_{CCO}$  = Output-side  $V_{CC}$

(2) Measured from input pin to same side ground.

## 6.12 Supply Current Characteristics—3.3V Supply

$V_{CC1} = V_{CC2} = 3.3V \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER                                                        | TEST CONDITIONS                                                                        |         | SUPPLY CURRENT     | MIN | TYP | MAX  | UNIT |
|------------------------------------------------------------------|----------------------------------------------------------------------------------------|---------|--------------------|-----|-----|------|------|
| ISO6420 (default high) and ISO6420F (default low, with F suffix) |                                                                                        |         |                    |     |     |      |      |
| Supply current - DC signal                                       | $V_I = V_{CC1}$ <sup>(1)</sup> (default high); $V_I = 0V$ (default low, with F suffix) |         | $I_{CC1}$          |     | 1.7 | 2.45 | mA   |
|                                                                  |                                                                                        |         | $I_{CC2}$          |     | 0.7 | 0.85 |      |
|                                                                  | $V_I = 0V$ (default high); $V_I = V_{CC1}$ (default low, with F suffix)                |         | $I_{CC1}$          |     | 5.3 | 6.55 |      |
|                                                                  |                                                                                        |         | $I_{CC2}$          |     | 0.6 | 0.7  |      |
| Supply current - AC signal                                       | All channels switching with square wave clock input; $C_L = 15pF$                      | 1Mbps   | $I_{CC1}$          |     | 3.8 | 4.4  |      |
|                                                                  |                                                                                        |         | $I_{CC2}$          |     | 0.7 | 0.85 |      |
|                                                                  |                                                                                        | 10Mbps  | $I_{CC1}$          |     | 3.8 | 4.5  |      |
|                                                                  |                                                                                        | 10Mbps  | $I_{CC2}$          |     | 1.3 | 1.55 |      |
|                                                                  |                                                                                        | 100Mbps | $I_{CC1}$          |     | 4.1 | 4.85 |      |
|                                                                  |                                                                                        | 100Mbps | $I_{CC2}$          |     | 7.5 | 8.5  |      |
| ISO6421 (default high) and ISO6421F (default low, with F suffix) |                                                                                        |         |                    |     |     |      |      |
| Supply current - DC signal                                       | $V_I = V_{CC1}$ <sup>(1)</sup> (default high); $V_I = 0V$ (default low, with F suffix) |         | $I_{CC1}, I_{CC2}$ |     | 1.7 | 2.4  | mA   |
|                                                                  | $V_I = 0V$ (default high); $V_I = V_{CC1}$ (default low, with F suffix)                |         | $I_{CC1}, I_{CC2}$ |     | 3.6 | 4.35 |      |
| Supply current - AC signal                                       | All channels switching with square wave clock input; $C_L = 15pF$                      | 1Mbps   | $I_{CC1}, I_{CC2}$ |     | 2.8 | 3.35 |      |
|                                                                  |                                                                                        | 10Mbps  | $I_{CC1}, I_{CC2}$ |     | 3.1 | 3.7  |      |
|                                                                  |                                                                                        | 100Mbps | $I_{CC1}, I_{CC2}$ |     | 6.3 | 7.3  |      |

(1)  $V_{CCI} = \text{Input-side } V_{CC}$

### 6.13 Electrical Characteristics—2.5V Supply

$V_{CC1} = V_{CC2} = 2.5V \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER         |                                                                                     | TEST CONDITIONS                                                                                                    | MIN                        | TYP                        | MAX | UNIT        |
|-------------------|-------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------|----------------------------|----------------------------|-----|-------------|
| $V_{OH(OUTx)}$    | OUTx (output) high-level output voltage                                             | $I_{OH} = -1mA$ ; See <a href="#">Section 7</a>                                                                    | $V_{CCO} - 0.1^{(1)}$      |                            |     | V           |
| $V_{OL(OUTx)}$    | OUTx (output) low-level output voltage                                              | $I_{OL} = 1mA$ ; See <a href="#">Section 7</a>                                                                     |                            |                            | 0.1 |             |
| $V_{IT+(INx)}$    | INx (input) switching threshold voltage, rising                                     |                                                                                                                    |                            | $0.7 \times V_{CCI}^{(1)}$ |     |             |
| $V_{IT-(INx)}$    | INx (input) switching threshold voltage, falling                                    |                                                                                                                    | $0.3 \times V_{CCI}^{(1)}$ |                            |     |             |
| $V_{I\_HYS(INx)}$ | INx (input) switching threshold voltage hysteresis                                  |                                                                                                                    | $0.1 \times V_{CCI}^{(1)}$ |                            |     |             |
| $I_{I(INx)}$      | INx (input) input current (default high device)                                     | HIGH Input Current: $V_{IH} = V_{CCI}^{(1)}$ at INx (leakage current)                                              |                            |                            | 1   | $\mu A$     |
|                   |                                                                                     | LOW Input Current: $V_{IL} = 0V$ at INx (leakage and current through default high pull-up resistance)              | -10                        |                            |     |             |
|                   | INx (input) input current (default low device, with F suffix)                       | HIGH Input Current: $V_{IH} = V_{CCI}^{(1)}$ at INx (leakage and current through default low pull-down resistance) |                            |                            | 10  |             |
|                   |                                                                                     | LOW Input Current: $V_{IL} = 0V$ at INx (leakage current)                                                          | -1                         |                            |     |             |
| CMTI_R            | Common mode transient immunity, device rated for reinforced isolation (DWV Package) | $V_I = V_{CC}$ or $0V$ , $V_{CM} = 1200V$ ; See <a href="#">Section 7</a>                                          | 200                        | 250                        |     | kV/ $\mu s$ |
| CMTI_B            | Common mode transient immunity, device rated for basic isolation (D Package )       | $V_I = V_{CC}$ or $0V$ , $V_{CM} = 1200V$ ; See <a href="#">Section 7</a>                                          | 150                        | 180                        |     | kV/ $\mu s$ |
| $C_i$             | Input Capacitance <sup>(2)</sup>                                                    | $V_I = V_{CC}/2 + 0.4 \times \sin(2\pi ft)$ , $f = 2MHz$ , $V_{CC} = 2.5V$                                         |                            | 1.35                       |     | pF          |

(1)  $V_{CCI}$  = Input-side  $V_{CC}$ ;  $V_{CCO}$  = Output-side  $V_{CC}$

(2) Measured from input pin to same side ground.

## 6.14 Supply Current Characteristics—2.5V Supply

$V_{CC1} = V_{CC2} = 2.5V \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER                                                        | TEST CONDITIONS                                                                        |         | SUPPLY CURRENT     | MIN | TYP | MAX  | UNIT |
|------------------------------------------------------------------|----------------------------------------------------------------------------------------|---------|--------------------|-----|-----|------|------|
| ISO6420 (default high) and ISO6420F (default low, with F suffix) |                                                                                        |         |                    |     |     |      |      |
| Supply current - DC signal                                       | $V_I = V_{CC1}$ <sup>(1)</sup> (default high); $V_I = 0V$ (default low, with F suffix) |         | $I_{CC1}$          |     | 1.7 | 2.45 | mA   |
|                                                                  |                                                                                        |         | $I_{CC2}$          |     | 0.7 | 0.85 |      |
|                                                                  | $V_I = 0V$ (default high); $V_I = V_{CC1}$ (default low, with F suffix)                |         | $I_{CC1}$          |     | 5.3 | 6.5  |      |
|                                                                  |                                                                                        |         | $I_{CC2}$          |     | 0.6 | 0.7  |      |
| Supply current - AC signal                                       | All channels switching with square wave clock input; $C_L = 15pF$                      | 1Mbps   | $I_{CC1}$          |     | 3.8 | 4.4  |      |
|                                                                  |                                                                                        |         | $I_{CC2}$          |     | 0.7 | 0.85 |      |
|                                                                  |                                                                                        | 10Mbps  | $I_{CC1}$          |     | 3.8 | 4.45 |      |
|                                                                  |                                                                                        |         | $I_{CC2}$          |     | 1.2 | 1.35 |      |
|                                                                  |                                                                                        | 100Mbps | $I_{CC1}$          |     | 4.1 | 4.75 |      |
|                                                                  |                                                                                        |         | $I_{CC2}$          |     | 5.9 | 6.7  |      |
| ISO6421 (default high) and ISO6421F (default low, with F suffix) |                                                                                        |         |                    |     |     |      |      |
| Supply current - DC signal                                       | $V_I = V_{CC1}$ <sup>(1)</sup> (default high); $V_I = 0V$ (default low, with F suffix) |         | $I_{CC1}, I_{CC2}$ |     | 1.7 | 2.4  | mA   |
|                                                                  | $V_I = 0V$ (default high); $V_I = V_{CC1}$ (default low, with F suffix)                |         | $I_{CC1}, I_{CC2}$ |     | 3.5 | 4.35 |      |
| Supply current - AC signal                                       | All channels switching with square wave clock input; $C_L = 15pF$                      | 1Mbps   | $I_{CC1}, I_{CC2}$ |     | 2.5 | 3.35 |      |
|                                                                  |                                                                                        | 10Mbps  | $I_{CC1}, I_{CC2}$ |     | 2.7 | 3.6  |      |
|                                                                  |                                                                                        | 100Mbps | $I_{CC1}, I_{CC2}$ |     | 5.5 | 6.35 |      |

(1)  $V_{CCI} = \text{Input-side } V_{CC}$

## 6.15 Switching Characteristics—5V Supply

$V_{CC1} = V_{CC2} = 5V \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER          |                                                             | TEST CONDITIONS                                                                                 | MIN | TYP  | MAX | UNIT    |
|--------------------|-------------------------------------------------------------|-------------------------------------------------------------------------------------------------|-----|------|-----|---------|
| $t_{PLH}, t_{PHL}$ | Propagation delay time                                      | at 100kbps                                                                                      | 4   | 6.2  | 10  | ns      |
| PWD                | Pulse width distortion <sup>(1)</sup> $ t_{PHL} - t_{PLH} $ | See <a href="#">Section 7</a>                                                                   |     | 0.2  | 1.8 | ns      |
| $t_{sk(o)}$        | Channel-to-channel output skew time <sup>(2)</sup>          | Same-direction channels                                                                         |     |      | 1.5 | ns      |
| $t_{sk(pp)}$       | Part-to-part skew time <sup>(3)</sup>                       |                                                                                                 |     |      | 3   | ns      |
| $t_r$              | Output signal rise time                                     | See <a href="#">Section 7</a>                                                                   |     |      | 3   | ns      |
| $t_f$              | Output signal fall time                                     |                                                                                                 |     |      | 3   | ns      |
| $t_{PU}$           | Time from $V_{CC}$ UVLO to valid output data                | $V_{CC}$ ramp < 1 $\mu$ s                                                                       |     |      | 90  | $\mu$ s |
| $t_{DO}$           | Default output delay time from input power loss             | Measured from the time $V_{CC}$ goes below $V_{CC\_UVLO-(MIN)}$ . See <a href="#">Section 7</a> |     | 0.05 | 0.1 | $\mu$ s |
| $t_{ie}$           | Time interval error                                         | $2^{16} - 1$ PRBS data at 100Mbps                                                               |     | 0.23 |     | ns      |

- (1) Also known as pulse skew.
- (2)  $t_{sk(o)}$  is the skew between outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical loads.
- (3)  $t_{sk(pp)}$  is the magnitude of the difference in propagation delay times between any terminals of different devices switching in the same direction while operating at identical supply voltages, temperature, input signals and loads.

## 6.16 Switching Characteristics—3.3V Supply

$V_{CC1} = V_{CC2} = 3.3V \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER          |                                                             | TEST CONDITIONS                                                                                 | MIN | TYP  | MAX  | UNIT    |
|--------------------|-------------------------------------------------------------|-------------------------------------------------------------------------------------------------|-----|------|------|---------|
| $t_{PLH}, t_{PHL}$ | Propagation delay time                                      | at 100kbps                                                                                      | 4   | 7    | 12   | ns      |
| PWD                | Pulse width distortion <sup>(1)</sup> $ t_{PHL} - t_{PLH} $ | See <a href="#">Section 7</a>                                                                   |     | 0.02 | 2.2  | ns      |
| $t_{sk(o)}$        | Channel-to-channel output skew time <sup>(2)</sup>          | Same-direction channels                                                                         |     |      | 1.5  | ns      |
| $t_{sk(pp)}$       | Part-to-part skew time <sup>(3)</sup>                       |                                                                                                 |     |      | 3    | ns      |
| $t_r$              | Output signal rise time                                     | See <a href="#">Section 7</a>                                                                   |     |      | 4    | ns      |
| $t_f$              | Output signal fall time                                     |                                                                                                 |     |      | 4    | ns      |
| $t_{PU}$           | Time from $V_{CC}$ UVLO to valid output data                | $V_{CC}$ ramp $< 1\mu s$                                                                        |     |      | 72.2 | $\mu s$ |
| $t_{DO}$           | Default output delay time from input power loss             | Measured from the time $V_{CC}$ goes below $V_{CC\_UVLO-(MIN)}$ . See <a href="#">Section 7</a> |     | 0.05 | 0.1  | $\mu s$ |
| $t_{ie}$           | Time interval error                                         | $2^{16} - 1$ PRBS data at 100Mbps                                                               |     | 0.24 |      | ns      |

(1) Also known as pulse skew.

(2)  $t_{sk(o)}$  is the skew between outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical loads.

(3)  $t_{sk(pp)}$  is the magnitude of the difference in propagation delay times between any terminals of different devices switching in the same direction while operating at identical supply voltages, temperature, input signals and loads.

## 6.17 Switching Characteristics—2.5V Supply

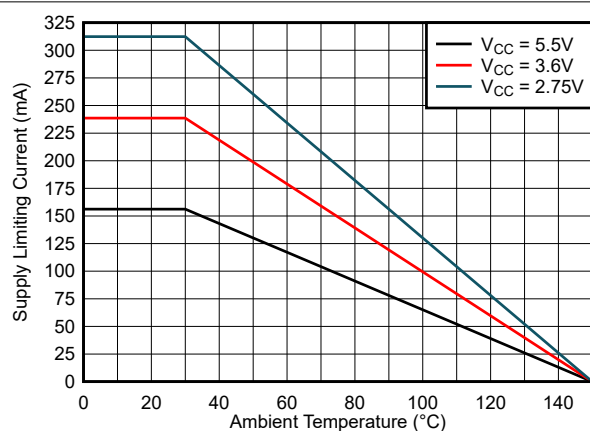
$V_{CC1} = V_{CC2} = 2.5V \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER          |                                                             | TEST CONDITIONS                                                                                 | MIN | TYP  | MAX  | UNIT    |
|--------------------|-------------------------------------------------------------|-------------------------------------------------------------------------------------------------|-----|------|------|---------|
| $t_{PLH}, t_{PHL}$ | Propagation delay time                                      | at 100kbps                                                                                      | 5   | 8.4  | 14.5 | ns      |
| PWD                | Pulse width distortion <sup>(1)</sup> $ t_{PHL} - t_{PLH} $ | See <a href="#">Section 7</a>                                                                   |     | 0.15 | 2.6  | ns      |
| $t_{sk(o)}$        | Channel-to-channel output skew time <sup>(2)</sup>          | Same-direction channels                                                                         |     |      | 1.5  | ns      |
| $t_{sk(pp)}$       | Part-to-part skew time <sup>(3)</sup>                       |                                                                                                 |     |      | 3    | ns      |
| $t_r$              | Output signal rise time                                     | See <a href="#">Section 7</a>                                                                   |     |      | 5    | ns      |
| $t_f$              | Output signal fall time                                     |                                                                                                 |     |      | 5    | ns      |
| $t_{PU}$           | Time from $V_{CC}$ UVLO to valid output data                | $V_{CC}$ ramp < 1 $\mu$ s                                                                       |     |      | 80   | $\mu$ s |
| $t_{DO}$           | Default output delay time from input power loss             | Measured from the time $V_{CC}$ goes below $V_{CC\_UVLO-(MIN)}$ . See <a href="#">Section 7</a> |     | 0.06 | 0.1  | $\mu$ s |
| $t_{ie}$           | Time interval error                                         | $2^{16} - 1$ PRBS data at 100Mbps                                                               |     | 0.27 |      | ns      |

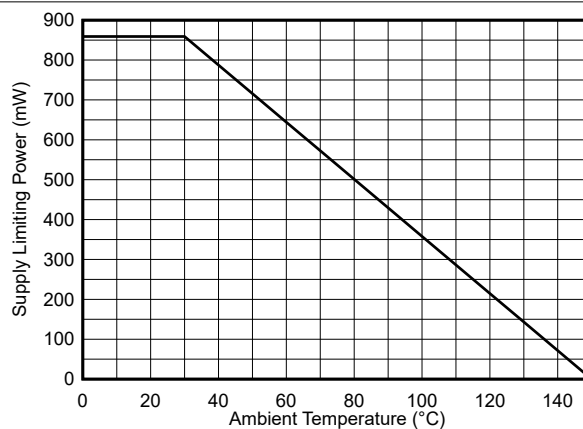
- (1) Also known as pulse skew.
- (2)  $t_{sk(o)}$  is the skew between outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical loads.
- (3)  $t_{sk(pp)}$  is the magnitude of the difference in propagation delay times between any terminals of different devices switching in the same direction while operating at identical supply voltages, temperature, input signals and loads.

## 6.18 Insulation Characteristics Curves

### Insulation Characteristics Curves for SOIC (D-8) Package

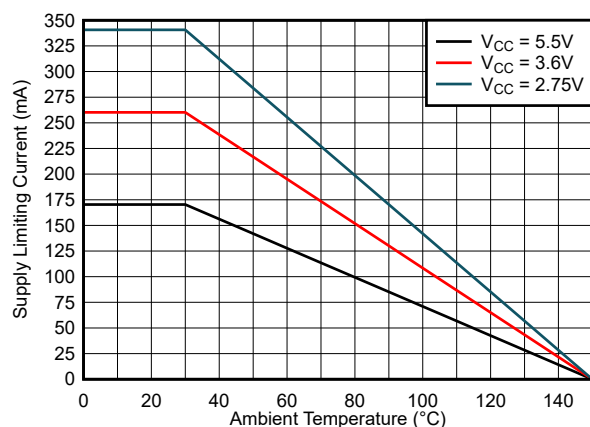


**Figure 6-1. Thermal Derating Curve for Safety Limiting Current for SOIC (D-8) Package**

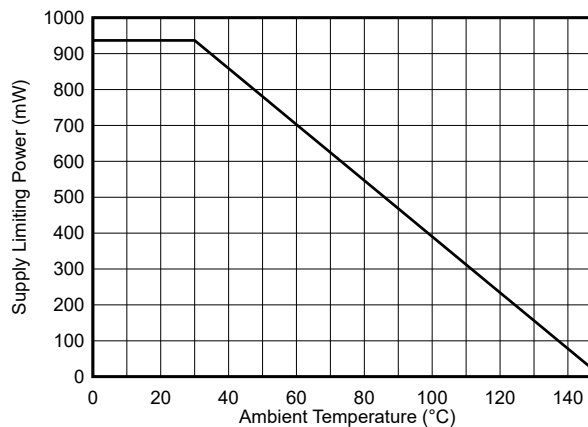


**Figure 6-2. Thermal Derating Curve for Safety Limiting Power for SOIC (D-8) Package**

### Insulation Characteristics Curves for Wide-SOIC (DWV-8) Package

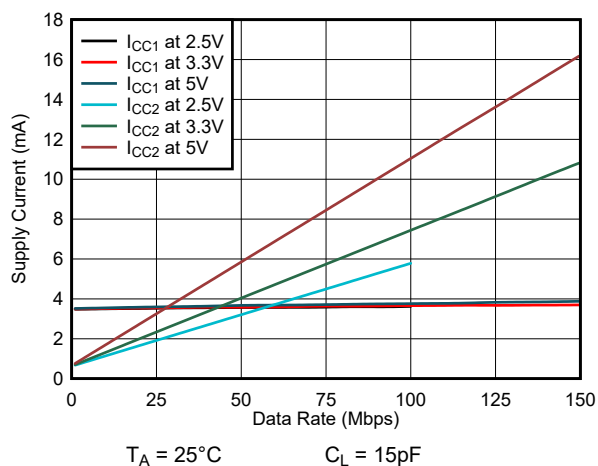


**Figure 6-3. Thermal Derating Curve for Safety Limiting Current for Wide-SOIC (DWV-8) Package**

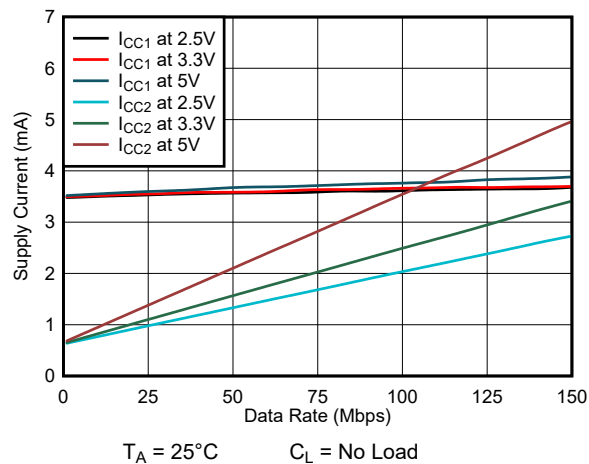


**Figure 6-4. Thermal Derating Curve for Safety Limiting Power for Wide-SOIC (DWV-8) Package**

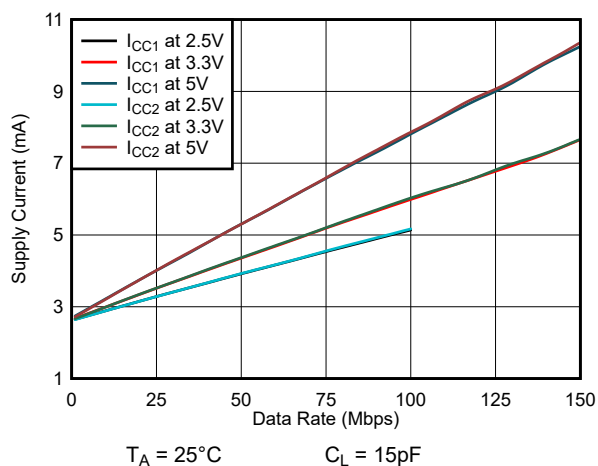
## 6.19 Typical Characteristics



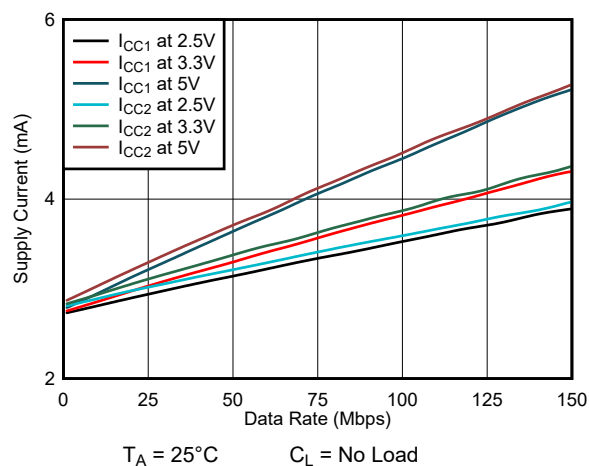
**Figure 6-5. ISO6420 or ISO6420F Supply Current vs Data Rate (With 15pF Load)**



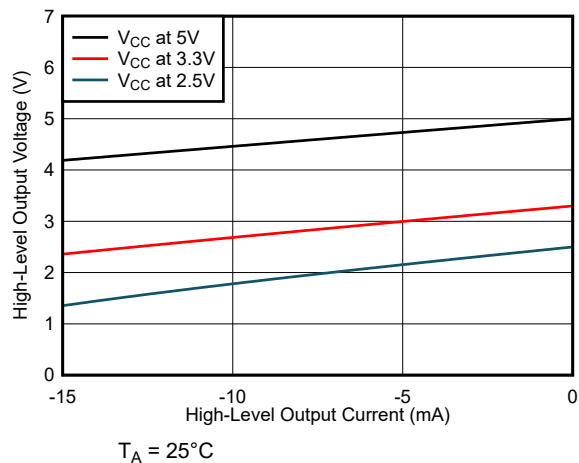
**Figure 6-6. ISO6420 or ISO6420F Supply Current vs Data Rate (With No Load)**



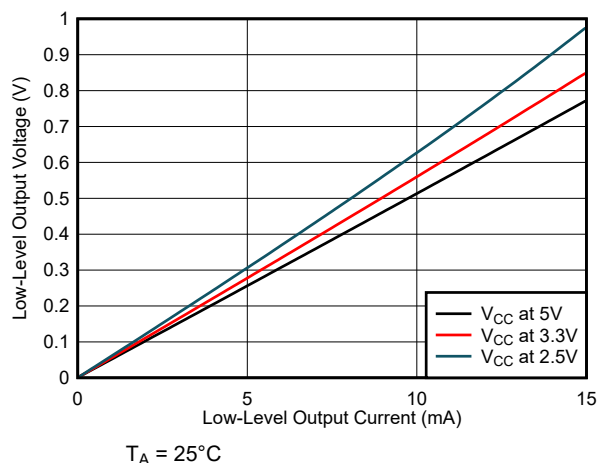
**Figure 6-7. ISO6421 or ISO6421F Supply Current vs Data Rate (With 15pF Load)**



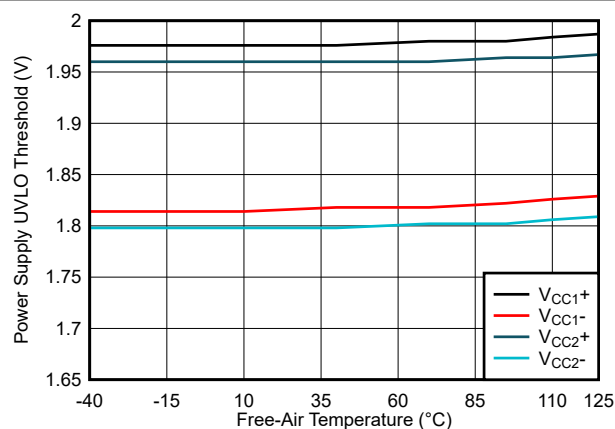
**Figure 6-8. ISO6421 or ISO6421F Supply Current vs Data Rate (With No Load)**



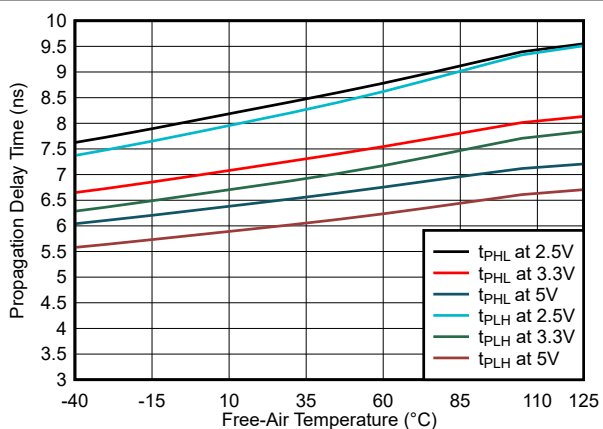
**Figure 6-9. High-Level Output Voltage vs High-level Output Current**



**Figure 6-10. Low-Level Output Voltage vs Low-Level Output Current**

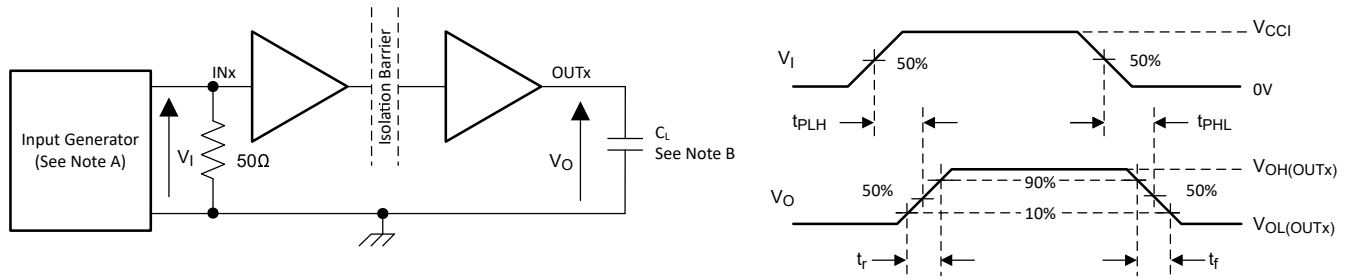


**Figure 6-11. Power Supply Undervoltage Threshold vs Free-Air Temperature**



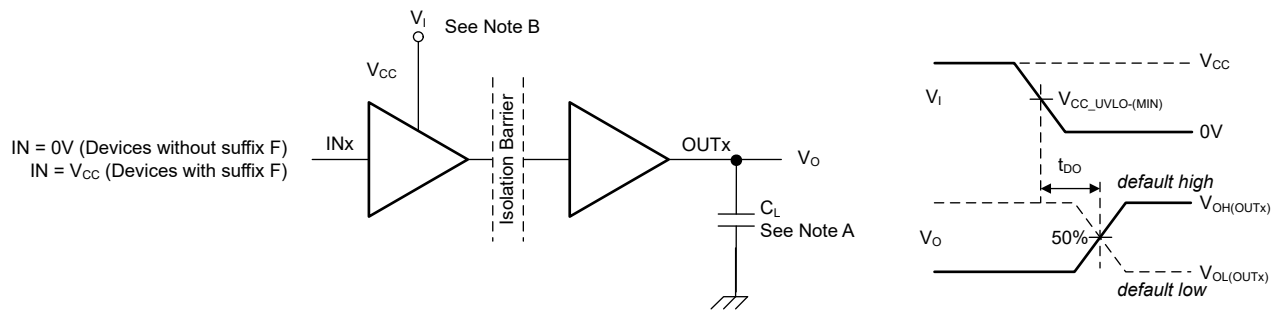
**Figure 6-12. Propagation Delay Time vs Free-Air Temperature**

## 7 Parameter Measurement Information



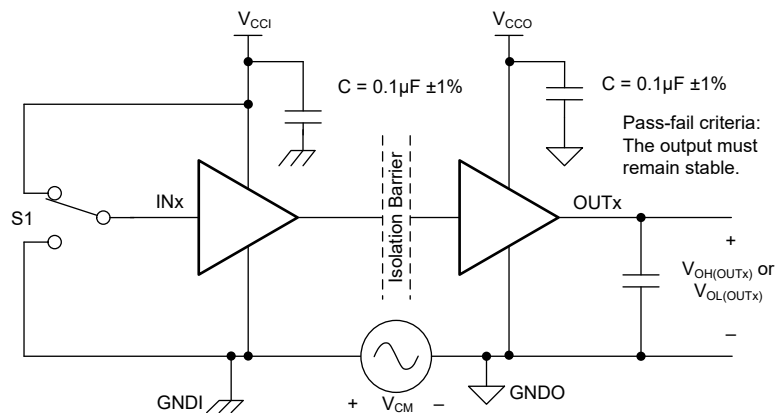
- A. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq 50\text{kHz}$ , 50% duty cycle,  $t_r \leq 1\text{ns}$ ,  $t_f \leq 1\text{ns}$ ,  $Z_0 = 50\Omega$ . At the input,  $50\Omega$  resistor is required to terminate INx (input) generator signal. The  $50\Omega$  resistor is not needed in the actual application.
- B.  $C_L = 15\text{pF}$  and includes instrumentation and fixture capacitance within  $\pm 20\%$ .

**Figure 7-1. Switching Characteristics Test Circuit and Voltage Waveforms**



- A.  $C_L = 15\text{pF}$  and includes instrumentation and fixture capacitance within  $\pm 20\%$ .
- B. Power Supply Ramp Rate =  $10\text{mV/ns}$

**Figure 7-2. Default Output Delay Time Test Circuit and Voltage Waveforms**



- A.  $C_L = 15\text{pF}$  and includes instrumentation and fixture capacitance within  $\pm 20\%$ .

**Figure 7-3. Common-Mode Transient Immunity Test Circuit**

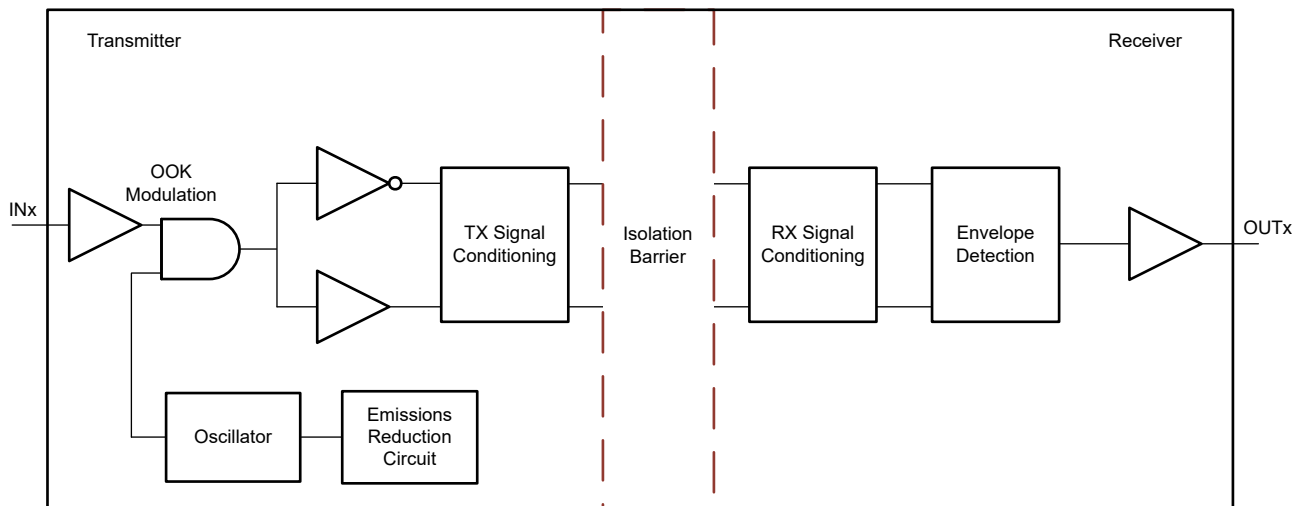
## 8 Detailed Description

### 8.1 Overview

The ISO642x family of devices have an ON-OFF keying (OOK) modulation scheme to transmit the digital data across a silicon dioxide based isolation barrier.

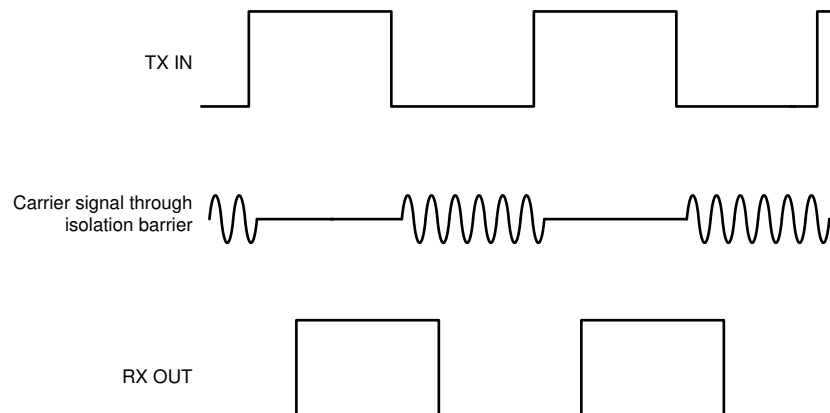
The transmitter sends a high frequency carrier across the barrier to represent one digital state and sends no signal to represent the other digital state. The receiver demodulates the signal after advanced signal conditioning and produces the output through a buffer stage. The ISO642x devices also incorporate advanced circuit techniques to maximize the CMTI performance and minimize the radiated emissions due to the high frequency carrier and IO buffer switching.

### 8.2 Functional Block Diagram



**Figure 8-1. Conceptual Block Diagram of an OOK Based Digital Isolator**

Figure 8-2 shows a conceptual detail of how the ON-OFF keying scheme works.



**Figure 8-2. On-Off Keying (OOK) Based Modulation Scheme**

## 8.3 Feature Description

Table 8-1 provides an overview of the device features.

**Table 8-1. Device Features**

| PART NUMBER | CHANNEL DIRECTION      | MAXIMUM DATA RATE | DEFAULT OUTPUT | PACKAGE     |
|-------------|------------------------|-------------------|----------------|-------------|
| ISO6420     | 2 Forward<br>0 Reverse | 150Mbps           | High           | D-8 , DWV-8 |
| ISO6420F    | 2 Forward<br>0 Reverse | 150Mbps           | Low            | D-8 , DWV-8 |
| ISO6421     | 1 Forward<br>1 Reverse | 150Mbps           | High           | D-8 , DWV-8 |
| ISO6421F    | 1 Forward<br>1 Reverse | 150Mbps           | Low            | D-8 , DWV-8 |

### 8.3.1 Electromagnetic Compatibility (EMC) Considerations

Many applications in harsh industrial environment are sensitive to disturbances such as electrostatic discharge (ESD), electrical fast transient (EFT), surge and electromagnetic emissions. These electromagnetic disturbances are defined and tested by international standards such as IEC 61000-4-x and CISPR 32. Although system-level performance and reliability depends, to a large extent, on the application board design and layout, the ISO642x family of devices incorporates many chip-level design techniques to help overall system robustness.

## 8.4 Device Functional Modes

The following table lists the functional modes for the ISO642x devices.

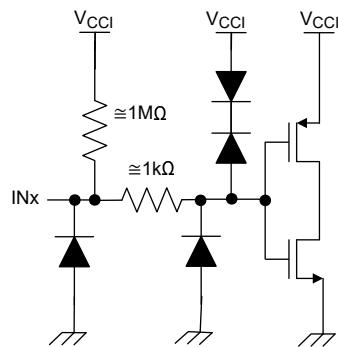
**Table 8-2. Function Table**

| V <sub>CCI</sub> <sup>(1)</sup> | V <sub>CCO</sub> | INPUT (IN <sub>x</sub> ) | OUTPUT (OUT <sub>x</sub> ) | COMMENTS                                                                                                                                                                                                                                                                                                                                                                                                                                                         |
|---------------------------------|------------------|--------------------------|----------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| PU                              | PU               | H                        | H                          | Normal Operation: A channel output assumes the logic state of the input.                                                                                                                                                                                                                                                                                                                                                                                         |
|                                 |                  | L                        | L                          |                                                                                                                                                                                                                                                                                                                                                                                                                                                                  |
|                                 |                  | Open                     | Default                    | Default mode: When IN <sub>x</sub> is open, the corresponding channel output goes to the default logic state. Default is <i>High</i> for ISO642x and <i>Low</i> for ISO642xF (with F suffix).                                                                                                                                                                                                                                                                    |
| PD                              | PU               | X                        | Default                    | Default mode: When V <sub>CCI</sub> is unpowered, a channel output assumes the logic state based on the selected default option. Default is <i>High</i> for ISO642x and <i>Low</i> for ISO642xF (with F suffix).<br>When V <sub>CCI</sub> transitions from unpowered to powered-up, a channel output assumes the logic state of the input.<br>When V <sub>CCI</sub> transitions from powered-up to unpowered, channel output assumes the selected default state. |
| X                               | PD               | X                        | Undetermined               | When V <sub>CCO</sub> is unpowered, a channel output is undetermined <sup>(2)</sup> . When V <sub>CCO</sub> transitions from unpowered to powered-up, a channel output assumes the logic state of the input.                                                                                                                                                                                                                                                     |

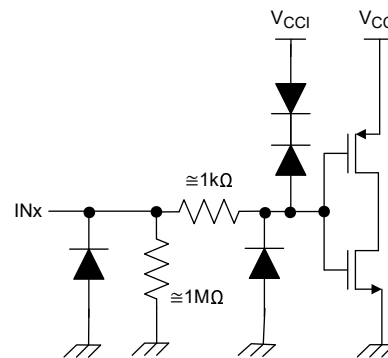
(1) V<sub>CCI</sub> = Input-side V<sub>CC</sub>; V<sub>CCO</sub> = Output-side V<sub>CC</sub>; PU = Powered up (V<sub>CC</sub> ≥ V<sub>CC\_RO(MIN)</sub>); PD = Powered down (V<sub>CC</sub> ≤ V<sub>CC\_UVLO-</sub>); X = Irrelevant; H = High level; L = Low level; Z = High Impedance

(2) The outputs are in undetermined state when V<sub>CC\_UVLO-</sub> ≤ V<sub>CCI</sub> or V<sub>CCO</sub> < V<sub>CC</sub> ≥ V<sub>CC\_RO(MIN)</sub>.

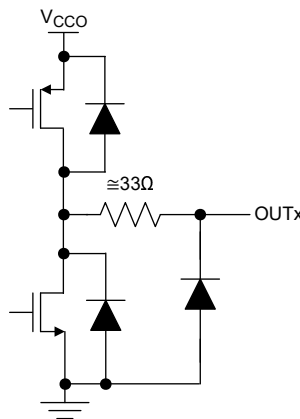
## 8.5 Device I/O Schematics



**Figure 8-3. Input (INx) Default High (Device Without F Suffix Device) Schematics**



**Figure 8-4. Input (INx) Default Low (Device With F Suffix Device) Schematics**



**Figure 8-5. Output (OUTx) Schematics**

### 8.5.1 Overvoltage Tolerant Input

The input pins of this device, INx, support input signal voltage in excess of the supply voltage ( $V_{CCI}$ ) on the input side of the device as long as the voltage on the inputs remains below the voltages listed in the [Recommended Operating Conditions](#) , and [Absolute Maximum Ratings](#) .

This allows the device to support input signal voltages on the inputs when the input supply,  $V_{CCI}$ , is unpowered. In this use case, the outputs transition to the default output state when the input side no longer has a valid supply.

These inputs also provide the capability of the inputs to down translate input signal voltages up to the  $V_{IMAX}$  in the [Recommended Operating Conditions](#) . For example, an input signal 5V high-level can be used while  $V_{CCI}$  is operating a 3.3V.

## 9 Application and Implementation

### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 9.1 Application Information

The ISO642x devices are high-performance, low power, dual-channel digital isolators. The ISO642x devices use single-ended CMOS-logic switching technology.

The supply voltage range is from 2.25V to 5.5V for both supplies,  $V_{CC1}$  and  $V_{CC2}$ . Since an isolation barrier separates the two sides, each side can be sourced independently with any voltage within the [Recommended Operating Conditions](#) section. As an example, supplying ISO642x  $V_{CC1}$  with 3.3V (which is within 2.25V to 5.5V) and  $V_{CC2}$  with 5V (which is also within 2.25V to 5.5V) is possible. You can use the digital isolator as a logic-level translator in addition to providing isolation. When designing with digital isolators, keep in mind that because of the single-ended design structure, digital isolators do not conform to any specific interface standard and are only intended for isolating single-ended CMOS or TTL digital signal lines. The isolator is typically placed between the data controller (that is, MCU or FPGA), and a data converter or a line transceiver, regardless of the interface type or standard.

### 9.2 Typical Application

Figure 9-1 shows the Universal Asynchronous Receiver/Transmitter (UART).

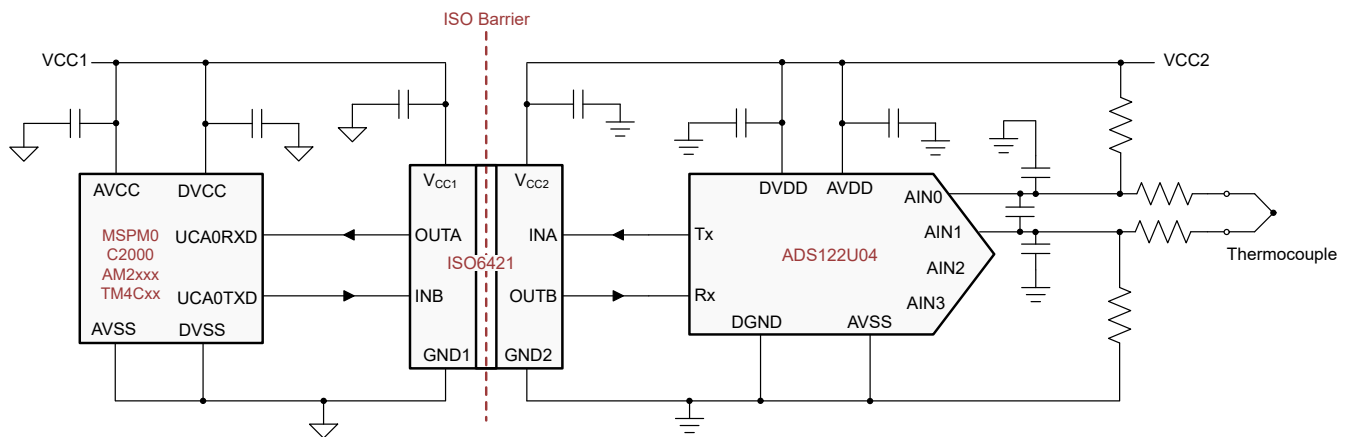


Figure 9-1. 2 Channel Typical Application

### 9.2.1 Design Requirements

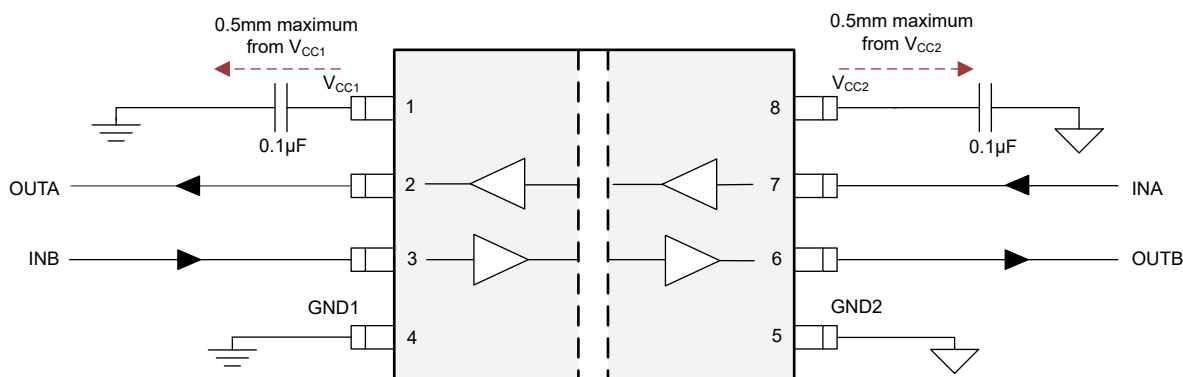
To design with these devices, use the parameters listed in [Table 9-1](#).

**Table 9-1. Design Parameters**

| PARAMETER                                       | VALUE         |
|-------------------------------------------------|---------------|
| Supply voltage, $V_{CC1}$ and $V_{CC2}$         | 2.25V to 5.5V |
| Decoupling capacitor between $V_{CC1}$ and GND1 | 0.1 $\mu$ F   |
| Decoupling capacitor from $V_{CC2}$ and GND2    | 0.1 $\mu$ F   |

### 9.2.2 Detailed Design Procedure

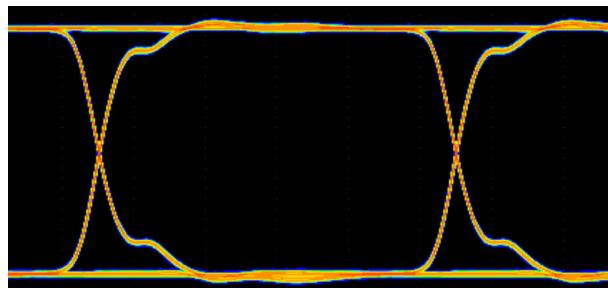
Unlike optocouplers, which require external components to improve performance, provide bias, or limit current, the ISO642x family of devices only require two external bypass capacitors to operate.



**Figure 9-2. Typical ISO642x Circuit**

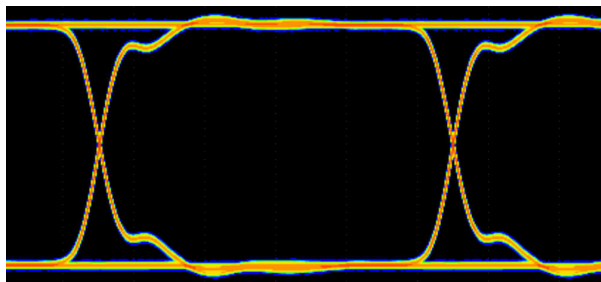
### 9.2.3 Application Curve

The following typical eye diagrams of the ISO642x family of devices indicates low jitter and wide open eye at 100Mbps.



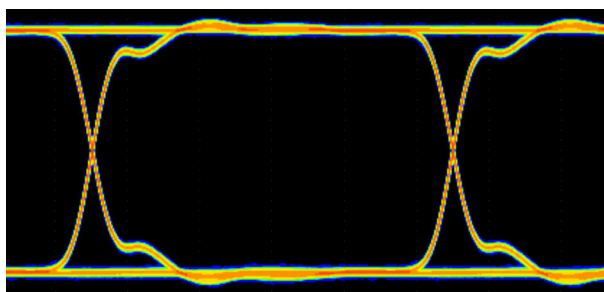
Horizontal 2ns / division, Vertical 1V / division.

**Figure 9-3. ISO642x Eye Diagram at 100Mbps  
PRBS  $2^{16} - 1$ , 5V and 25°C**



Horizontal 2ns / division, Vertical 500mV / division.

**Figure 9-4. ISO642x Eye Diagram at 100Mbps  
PRBS  $2^{16} - 1$ , 3.3V and 25°C**



Horizontal 2ns / division, Vertical 500mV / division.

**Figure 9-5. ISO642x Eye Diagram at 100Mbps PRBS  $2^{16} - 1$ , 2.5V and 25°C**

## 9.3 Power Supply Recommendations

To provide reliable operation at data rates and supply voltages, a 0.1µF bypass capacitor is recommended at the input and output supply pins ( $V_{CC1}$  and  $V_{CC2}$ ). The capacitors must be placed as close to the supply pins as possible. If only a single primary-side power supply is available in an application, isolated power can be generated for the secondary-side with the help of a transformer driver. For industrial applications, please use Texas Instruments' [SN6501](#) or [SN6505B](#). For such applications, detailed power supply design and transformer selection recommendations are available in [SN6501 Transformer Driver for Isolated Power Supplies](#) or [SN6505B Low-noise, 1A Transformer Drivers for Isolated Power Supplies](#).

## 9.4 Layout

### 9.4.1 Layout Guidelines

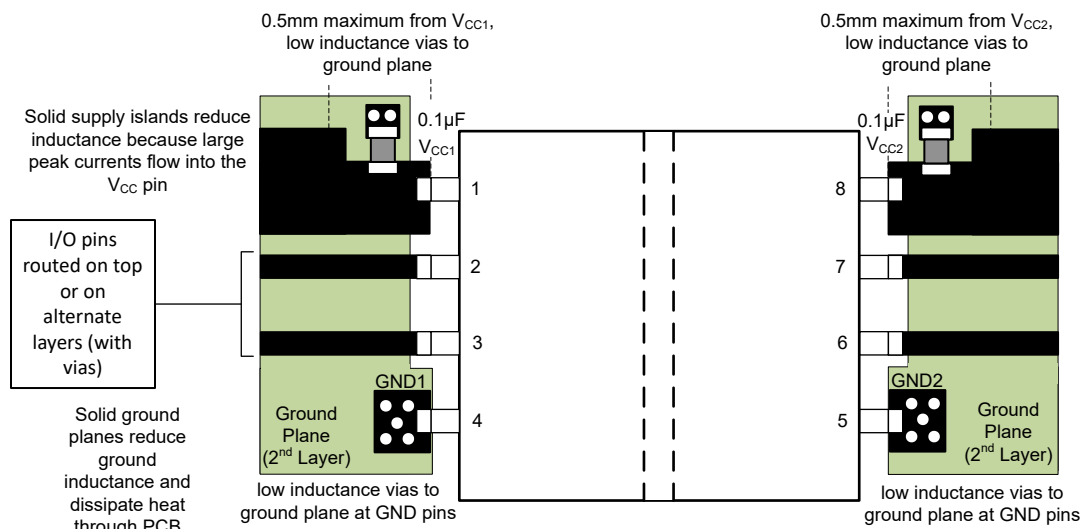
A minimum of two layers is required to accomplish a cost optimized and low EMI PCB design. To further improve EMI, a four layer board can be used (see [Layout Example Schematic](#)). Layer stacking for a four layer board must be in the following order (top-to-bottom): high-speed signal layer, ground plane, power plane and low-frequency signal layer.

- Routing the high-speed traces on the top layer avoids the use of vias (and the introduction of the inductances) and allows for clean interconnects between the isolator and the transmitter and receiver circuits of the data link.
- Placing a solid ground plane next to the high-speed signal layer establishes controlled impedance for transmission line interconnects and provides an excellent low-inductance path for the return current flow.
- Placing the power plane next to the ground plane creates additional high-frequency bypass capacitance of approximately 100pF/inch<sup>2</sup>.
- Routing the slower speed control signals on the bottom layer allows for greater flexibility as these signal links typically have margin to tolerate discontinuities such as vias.

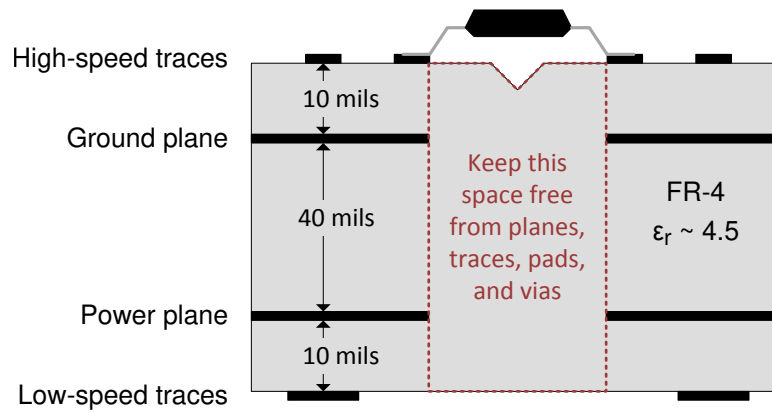
If an additional supply voltage plane or signal layer is needed, add a second power or ground plane system to the stack to keep the planes symmetrical. This design makes the stack mechanically stable and prevents warping. Also the power and ground plane of each power system can be placed closer together, thus increasing the high-frequency bypass capacitance significantly.

For detailed layout recommendations, refer to the [Digital Isolator Design Guide](#) application note.

### 9.4.2 Layout Example



**Figure 9-6. Layout Example**



**Figure 9-7. Layout Example PCB Cross Section**

## 10 Device and Documentation Support

### 10.1 Documentation Support

#### 10.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, [ISO6420 Technical Documents](#)
- Texas Instruments, [ISO6421 Technical Documents](#)
- Texas Instruments, [SN6501 Transformer Driver for Isolated Power Supplies](#), data sheet

### 10.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](#). Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 10.3 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

### 10.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

### 10.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 10.6 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

## 11 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| Changes from Revision * (August 2025) to Revision A (March 2026)                                                                                                                                                                                                                                                                                 | Page |
|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|
| • Updated status of the data sheet to mixed status for both production and advanced information devices, refer to the Packaging Information table on the Package Option Addendum page in the <a href="#">Mechanical, Packaging, and Orderable Information</a> section for Production or Preproduction status for specific device and package.... | 1    |
| • Updated the CMTI minimum and typical values throughout the document for CMTI_B (devices with basic insulation). .....                                                                                                                                                                                                                          | 1    |
| • Added Functional-Safety Capable. ....                                                                                                                                                                                                                                                                                                          | 1    |
| • Deleted planned CSA certification and added planned UL 1577 and CSA CAS Notice No. 5A certification throughout the document. Removed IEC 60601-1 from planned certifications. ....                                                                                                                                                             | 1    |
| • Updated the numbering format for tables, figures, and cross-references throughout the document.....                                                                                                                                                                                                                                            | 1    |
| • Updated the typical value for the ICC1 and ICC2 for 1Mbps and 10Mbps in the Electrical Characteristics - 2.5V Supply sub-section of the <a href="#">Specifications</a> section.....                                                                                                                                                            | 5    |
| • Updated the C <sub>i</sub> typical value and CMTI_B minimum and typical value in all Electrical Characteristics for all supply voltages sub-sections of the <a href="#">Specifications</a> section.....                                                                                                                                        | 5    |

- 
- Updated the typical value for the PWD,  $t_{DO}$ , and  $t_{ie}$  in all Switching Characteristics for all supply voltages sub-sections of the [Specifications](#) section.....5
  - Updated the maximum value for  $t_{pU}$  in the Switching Characteristics - 2.5V Supply sub-section of the [Specifications](#) section.....5
  - Added the [Typical Characteristics](#) section to the data sheet. ....21
- 

## 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

## PACKAGING INFORMATION

| Orderable part number         | Status<br>(1) | Material type<br>(2) | Package   Pins | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|-------------------------------|---------------|----------------------|----------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">ISO6421DR</a>     | Active        | Production           | SOIC (D)   8   | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | 6421                |
| <a href="#">XISO6420DR</a>    | Active        | Preproduction        | SOIC (D)   8   | 2500   LARGE T&R      | -           | Call TI                              | Call TI                           | -40 to 125   |                     |
| <a href="#">XISO6420DWVR</a>  | Active        | Preproduction        | SOIC (DWV)   8 | 1000   LARGE T&R      | -           | Call TI                              | Call TI                           | -40 to 125   |                     |
| <a href="#">XISO6420FDR</a>   | Active        | Preproduction        | SOIC (D)   8   | 2500   LARGE T&R      | -           | Call TI                              | Call TI                           | -40 to 125   |                     |
| <a href="#">XISO6420FDWVR</a> | Active        | Preproduction        | SOIC (DWV)   8 | 1000   LARGE T&R      | -           | Call TI                              | Call TI                           | -40 to 125   |                     |
| <a href="#">XISO6421DR</a>    | Active        | Preproduction        | SOIC (D)   8   | 2500   LARGE T&R      | -           | Call TI                              | Call TI                           | -40 to 125   |                     |
| <a href="#">XISO6421DWVR</a>  | Active        | Preproduction        | SOIC (DWV)   8 | 1000   LARGE T&R      | -           | Call TI                              | Call TI                           | -40 to 125   |                     |
| <a href="#">XISO6421FDR</a>   | Active        | Preproduction        | SOIC (D)   8   | 2500   LARGE T&R      | -           | Call TI                              | Call TI                           | -40 to 125   |                     |
| <a href="#">XISO6421FDWVR</a> | Active        | Preproduction        | SOIC (DWV)   8 | 1000   LARGE T&R      | -           | Call TI                              | Call TI                           | -40 to 125   |                     |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

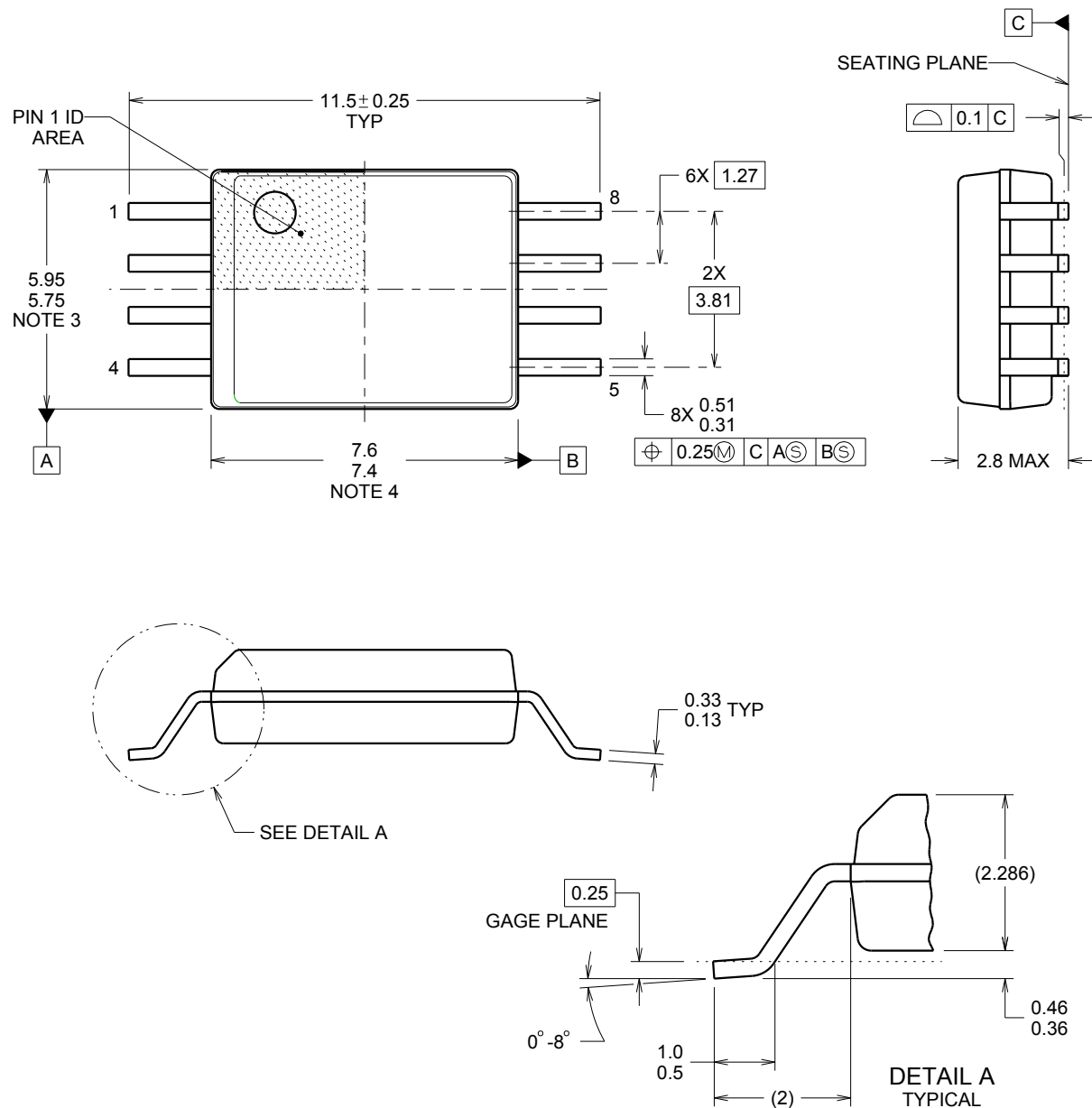
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

DWV0008A



SOIC - 2.8 mm max height

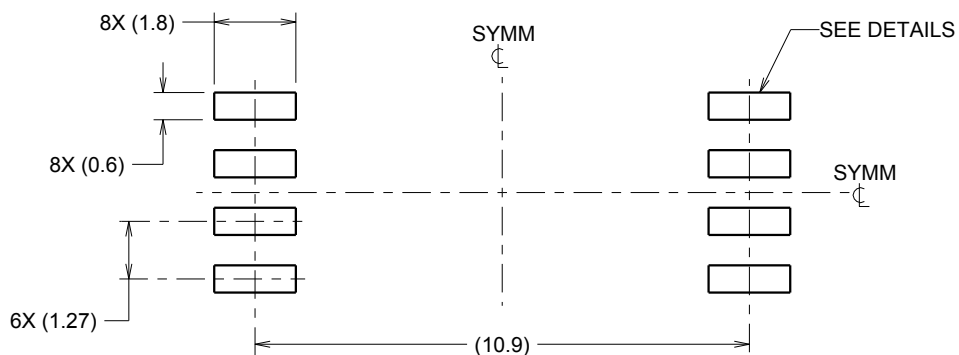
SOIC



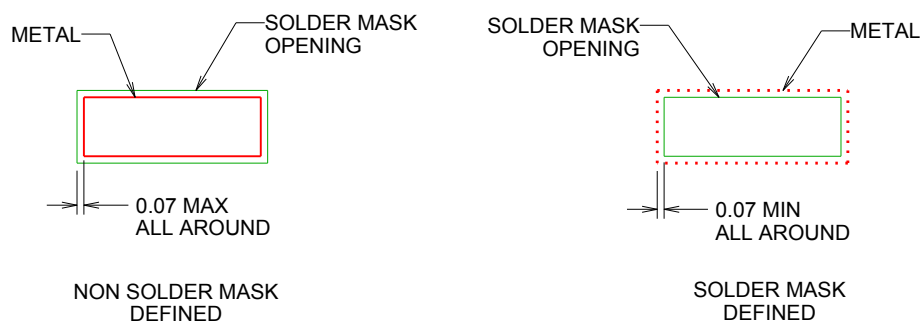
4218796/A 09/2013

## NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.



**LAND PATTERN EXAMPLE**  
9.1 mm NOMINAL CLEARANCE/CREEPAGE  
SCALE:6X

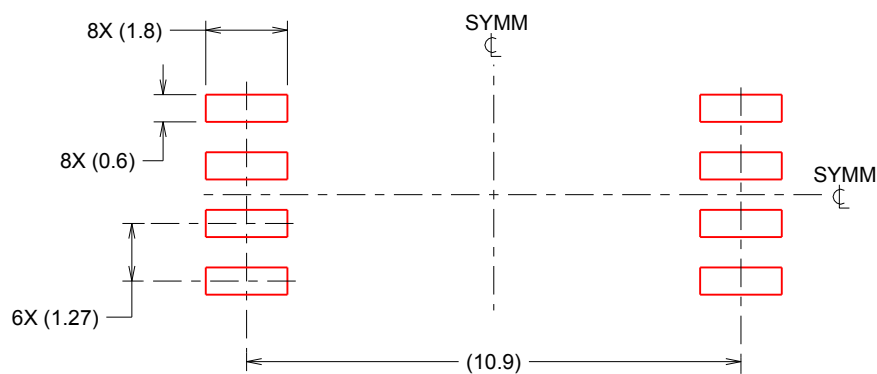


**SOLDER MASK DETAILS**

4218796/A 09/2013

NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE  
 BASED ON 0.125 mm THICK STENCIL  
 SCALE:6X

4218796/A 09/2013

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.



## PACKAGE OUTLINE

**SOIC - 1.75 mm max height**

SMALL OUTLINE INTEGRATED CIRCUIT



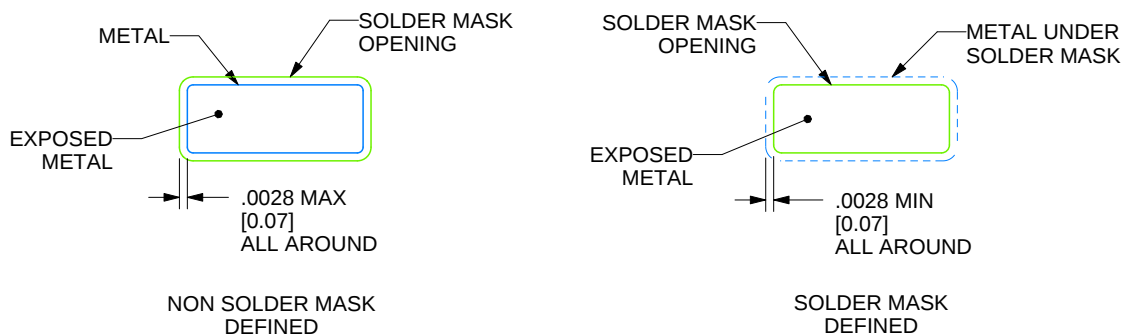
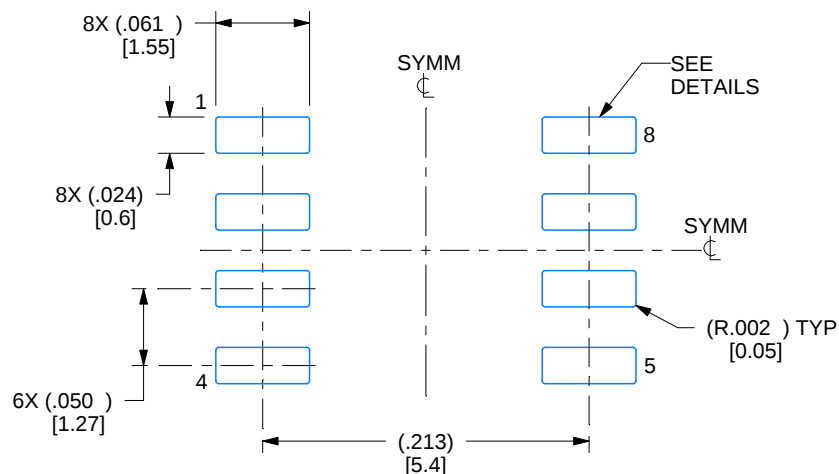
1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

# EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

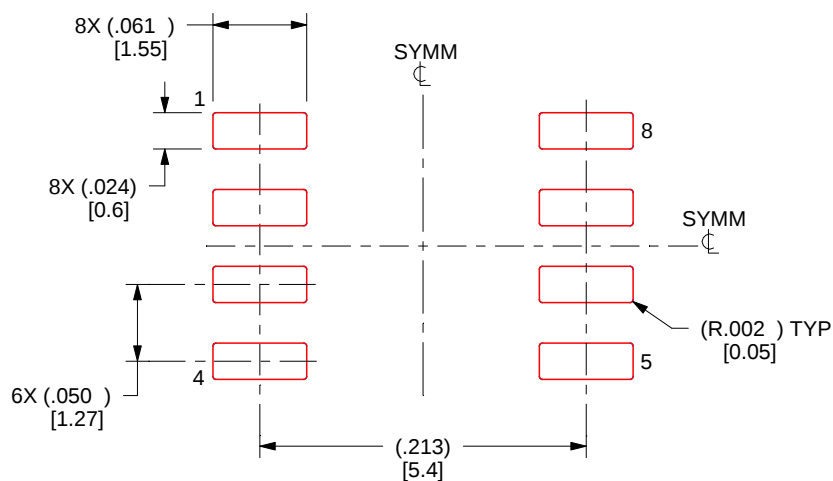
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

## EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE  
BASED ON .005 INCH [0.125 MM] THICK STENCIL  
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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